



中国科学院高能物理研究所  
*Institute of High Energy Physics*  
*Chinese Academy of Sciences*

# Simulation of Detector Response in the Drift Chamber

Wenxing Fang (IHEP)

On behalf of CEPC drift chamber working group

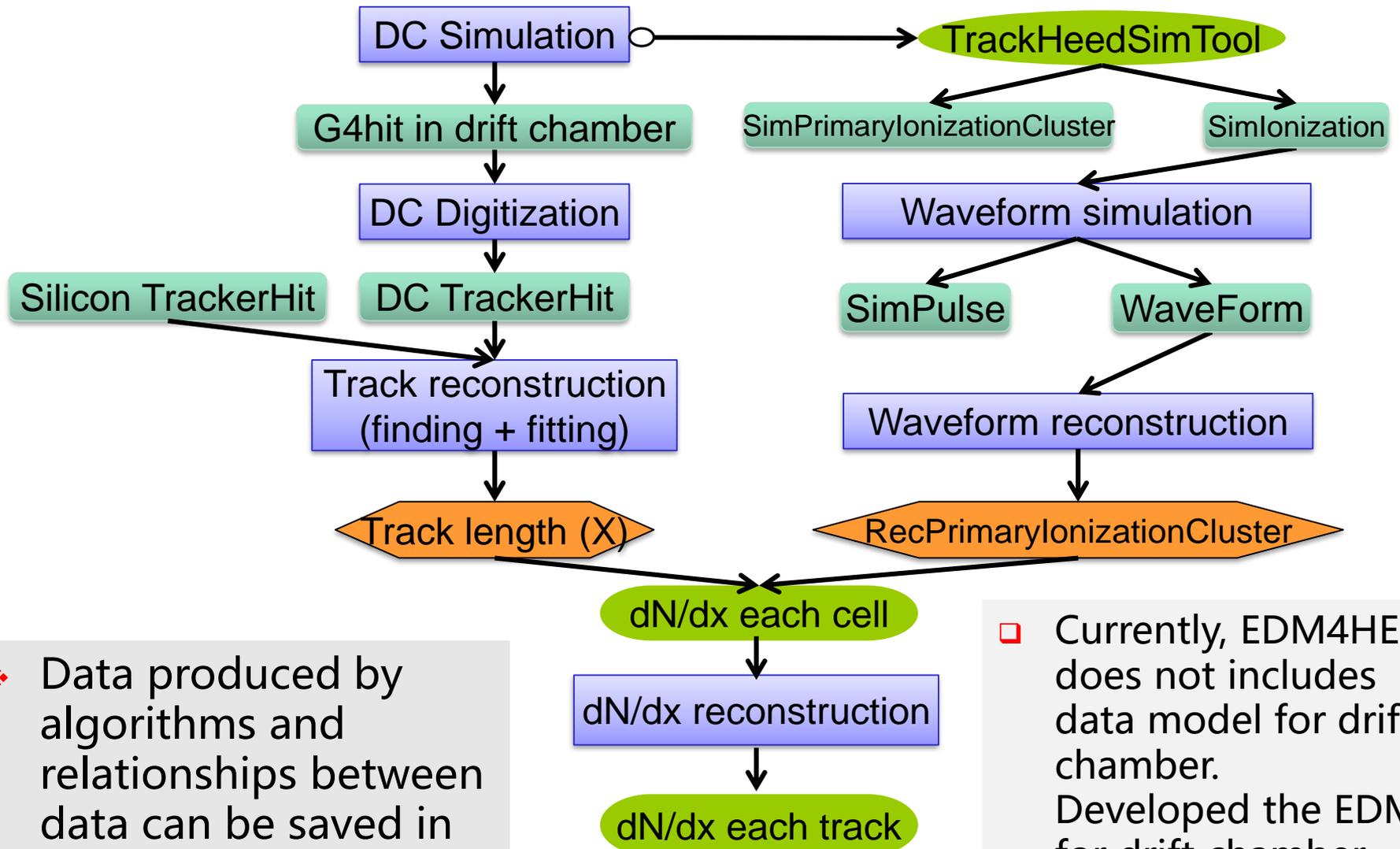
CEPC International Workshop 2021.11.11

# Motivation

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- ❑ CEPC is a precise experiment
  - ❑ Higgs, W, Z, ...
  - ❑ PID performance is important
- ❑ From the previous [study](#), the primary ionization counting (dN/dx) method has potential to achieve very good PID performance (<3% resolution)
- ❑ To apply this method to the CEPC experiment, more studies are required by using precise dN/dx simulation
- ❑ All the studies of this presentation were performed with the software developed in the CEPCSW

# Simulation and reconstruction workflow



❖ Data produced by algorithms and relationships between data can be saved in EDM4hep for analysis

❑ Currently, EDM4HEP does not include data model for drift chamber. Developed the EDM for drift chamber based on PODIO

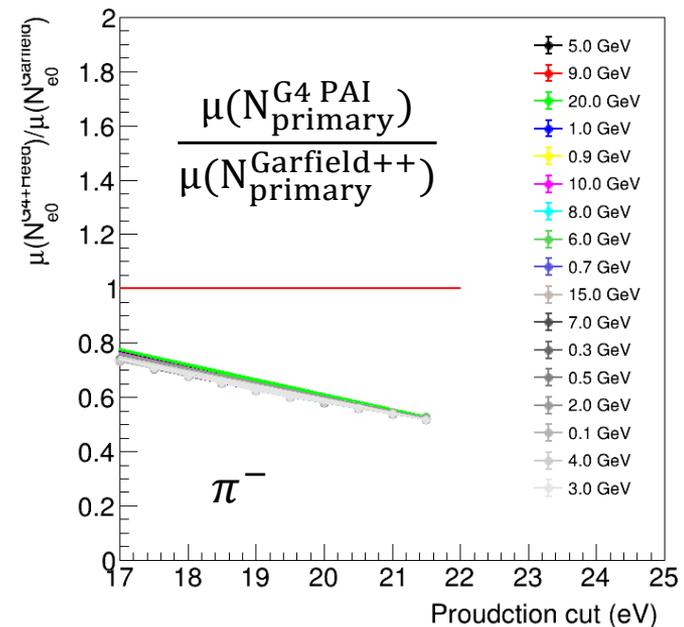
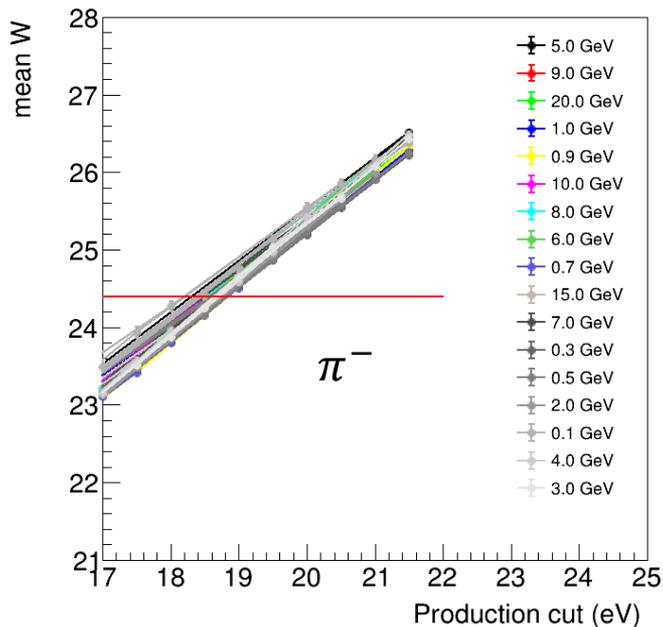
# Ionization simulation in DC

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- ❑ As we know Geant4 can not simulate the ionization process properly (arXiv:2105.07064)
- ❑ Garfield++ is commonly used for precise ionization simulation for simple geometry
- ❑ In order to do a detailed drift chamber simulation, including particle interaction with detector materials, ionization in gas, drift and avalanche processes in drift chamber cell, combining Geant4 and Garfield++ is needed
- ❑ This paper [“Interfacing Geant4, Garfield++ and Degrad for the Simulation of Gaseous Detectors”](#) introduces some ways to combine Geant4 and Garfield++ to get correct energy deposition or total number of ionized electrons (adopted by COMET experiment)
- ❑ However, it can not give both correct number of primary ionization and total number of ionized electrons (see next slide)

# Ionization simulation in CEPCSW (G4 PAI)

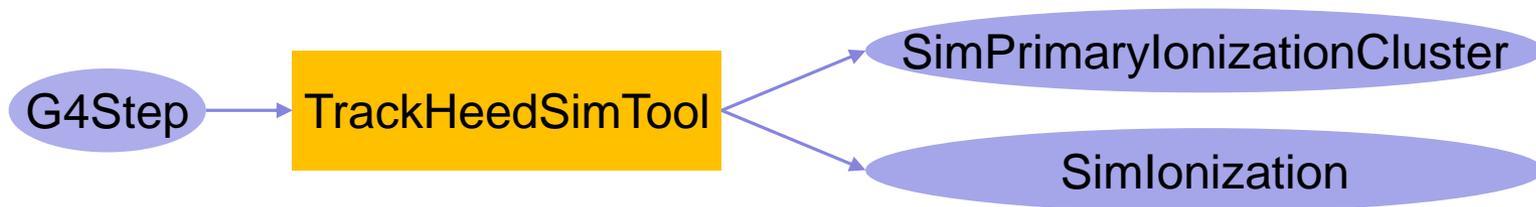
- ❖ It was found that the primary ionization produced by this method is much less than Garfield++
- ❖ Confirmed with authors



# Ionization simulation in CEPCSW

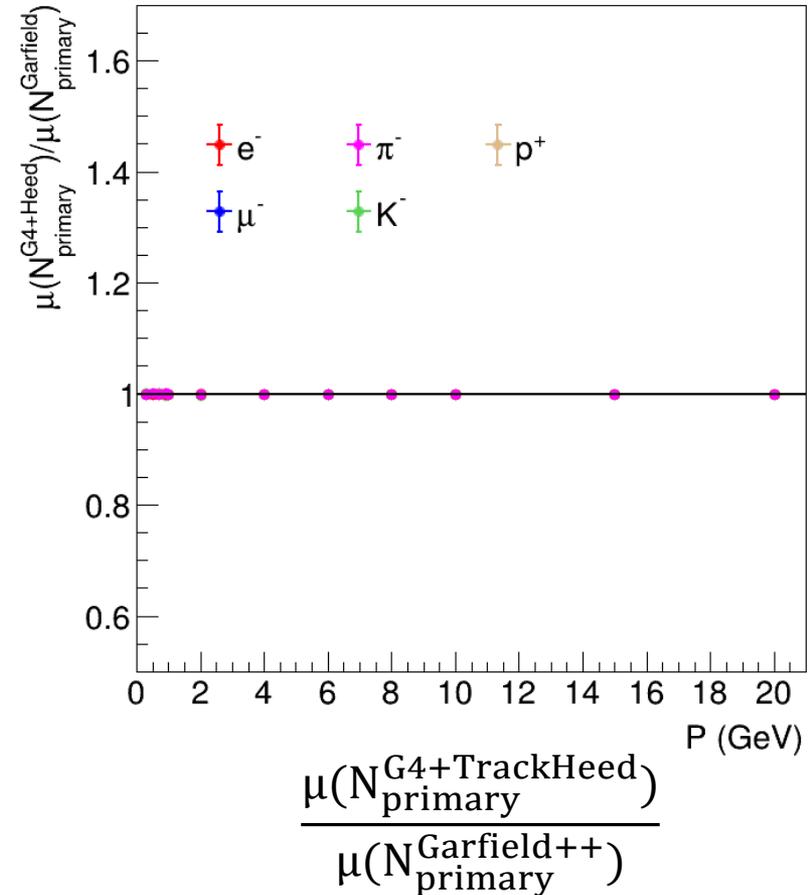
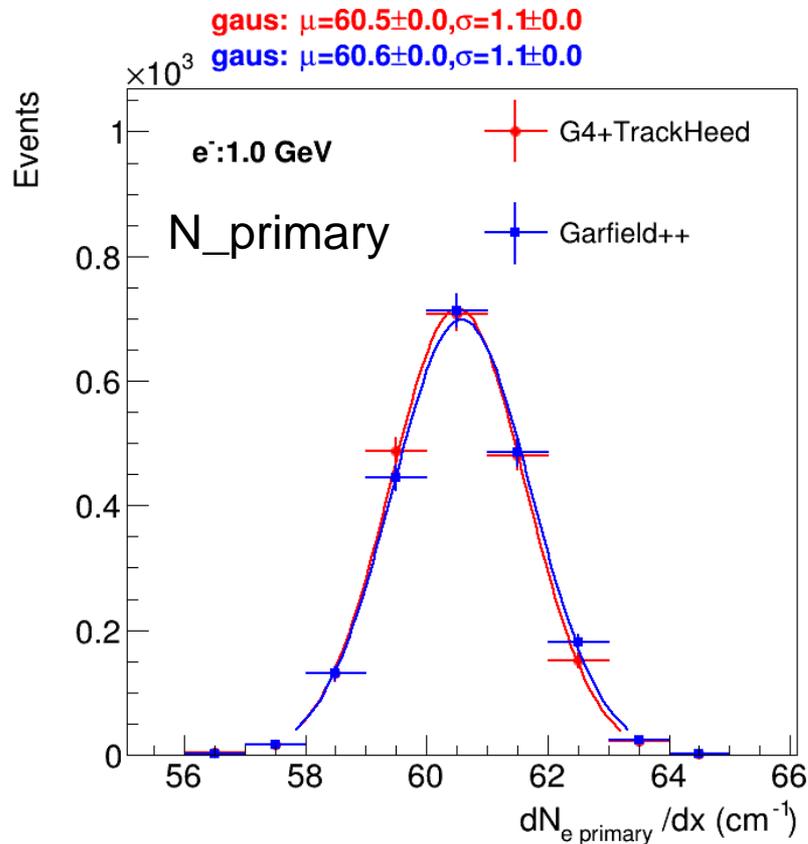
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- ❖ Combining Geant4 and Garfield++ at G4Step level
- ❖ TrackHeedSimTool is created for this task
  - Input: G4Step information (particle type, initial position and momenta, ionization path length)
  - Use TrackHeed (used by Garfield++) to simulate one step length (or multi-step length for speed up) ionization (new API added to Garfield++ [PR](#))
  - Output: primary and total ionization information (contains position, time, cell id), saved in EDM (SimTrackerHit collection)
  - The kinetic energy of G4Track will be updated according to the energy loss in the ionization
  - Non-uniform magnetic field can be handled easily



# Ionization simulation performance

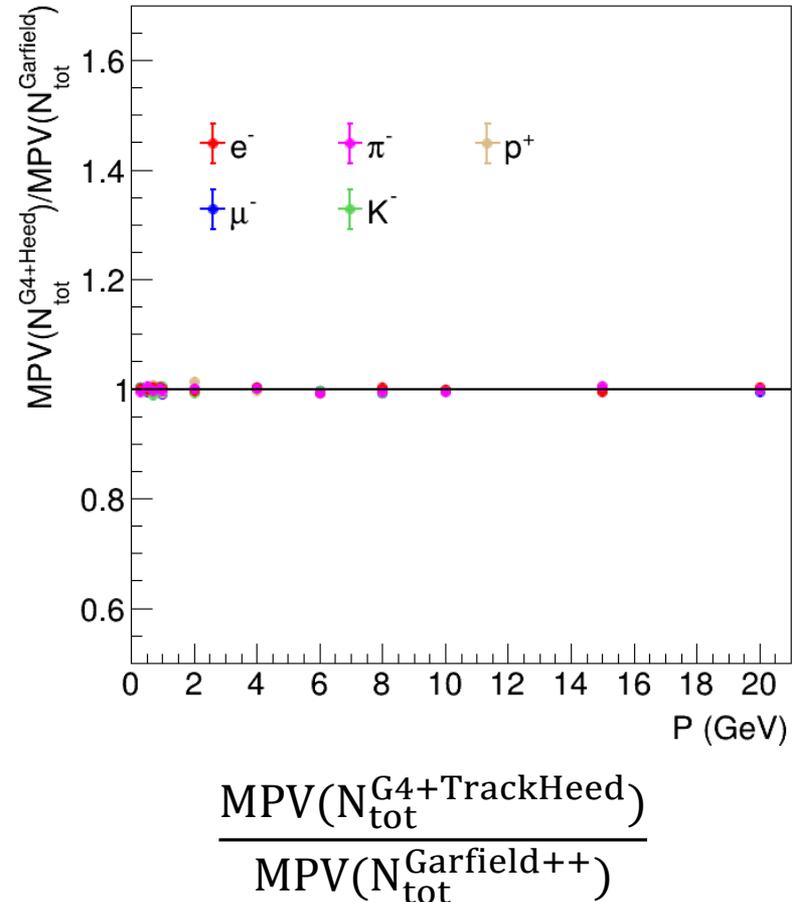
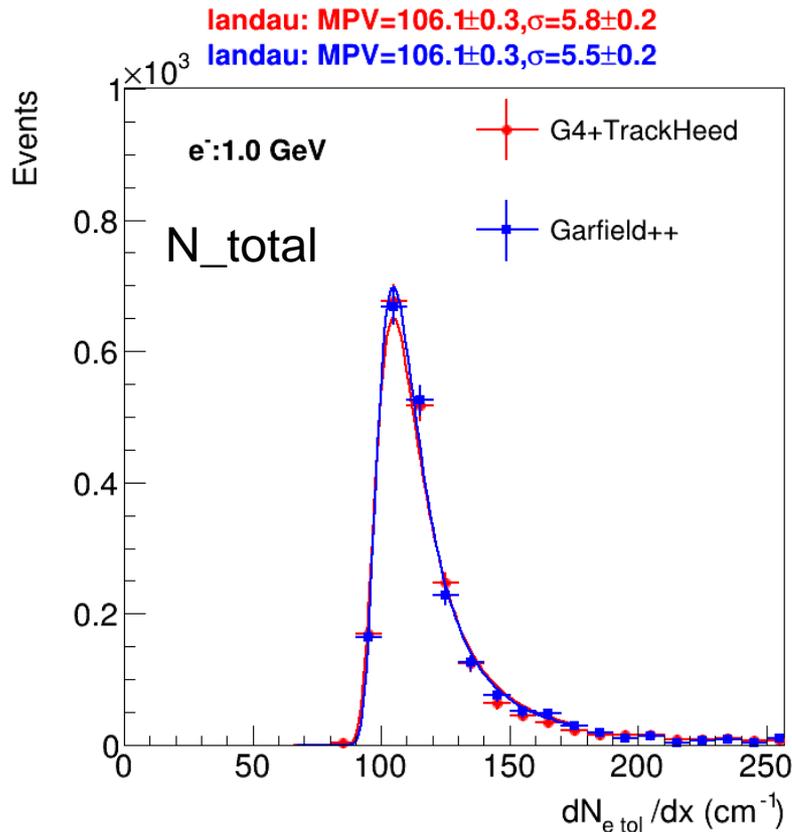
❖ Gas: 50% He + 50 % C<sub>4</sub>H<sub>10</sub>



Consistent with Garfield++ standalone simulation results, see backup for more details

# Ionization simulation performance

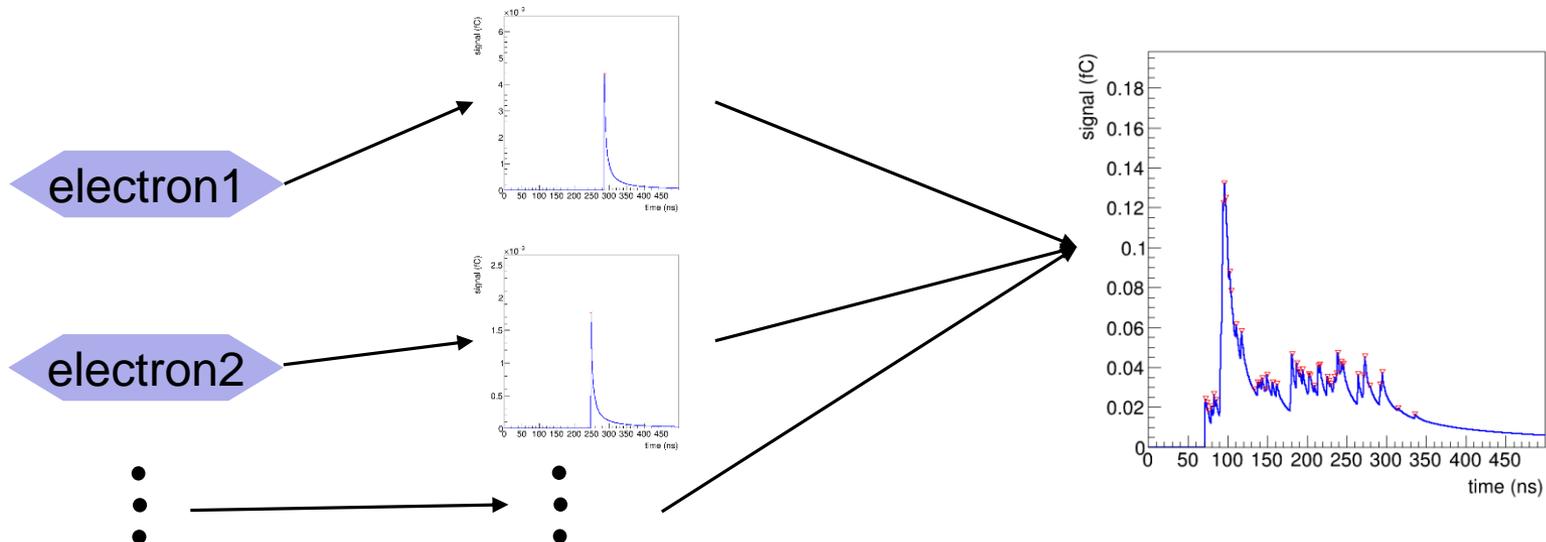
❖ Gas: 50% He + 50 % C<sub>4</sub>H<sub>10</sub>



Consistent with Garfield++ standalone simulation results, see backup for more details

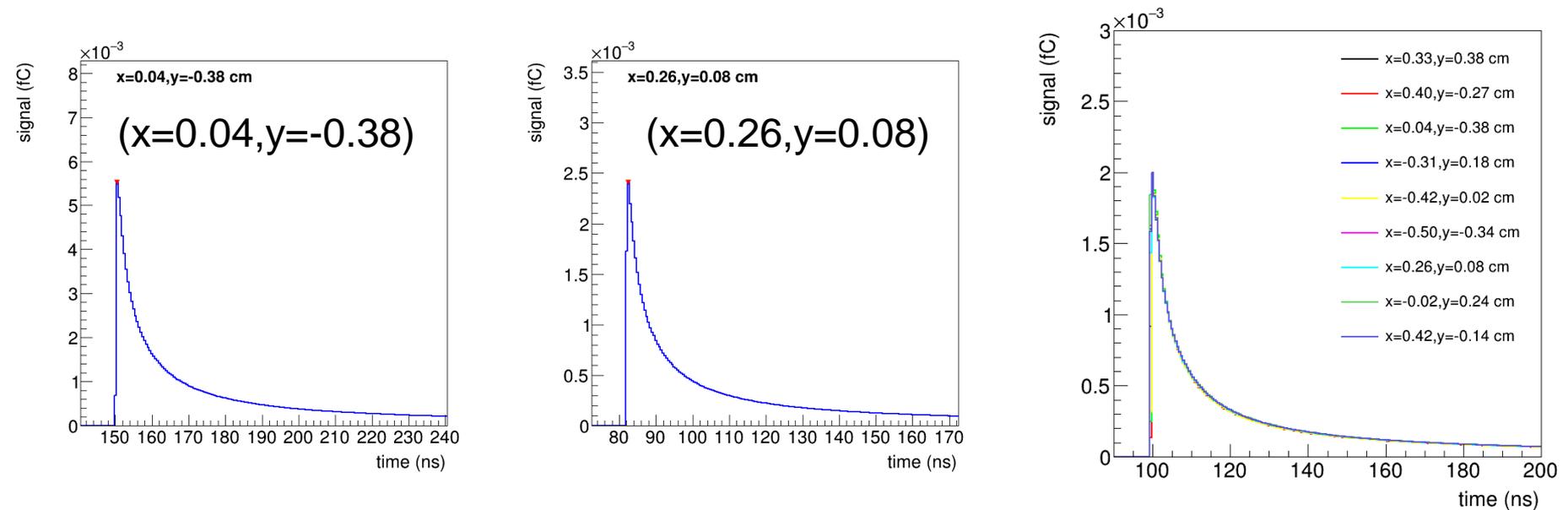
# Signal response simulation

- ❖ From ionized electrons to signal response simulation
  - Using Garfield++, simulate the drift and avalanche of electron and drift of ions. Extremely time consuming,  $\mathcal{O}(1)$  to  $\mathcal{O}(10)$  seconds for different gas just for one electron
  - Going to use parameterization (fast simulation) method ( parameters are based on Garfield++ simulation results), will be much faster
    - For each electron, simulate its own pulse
    - As done by Garfield++, piling up all pulses from same drift chamber cell gives final signal response



# Garfield++ simulation

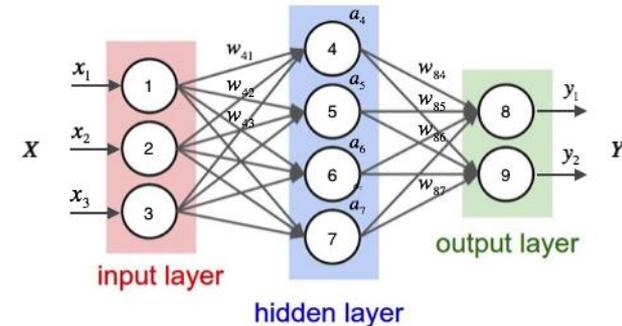
- ❖ Performed single electron simulations using Garfield++
- ❖ All single electron pulses are similar after normalization. For example, if its peak position is shifted to some value (e.g. 100 ns) and its peak value is scaled to some value (e.g.  $2 \times 10^{-3}$ )



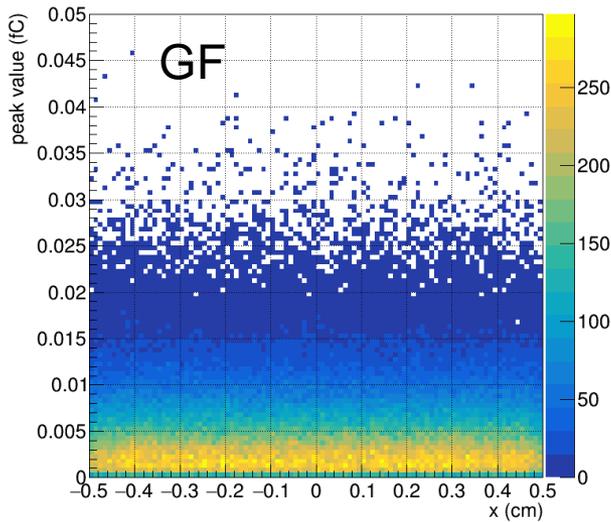
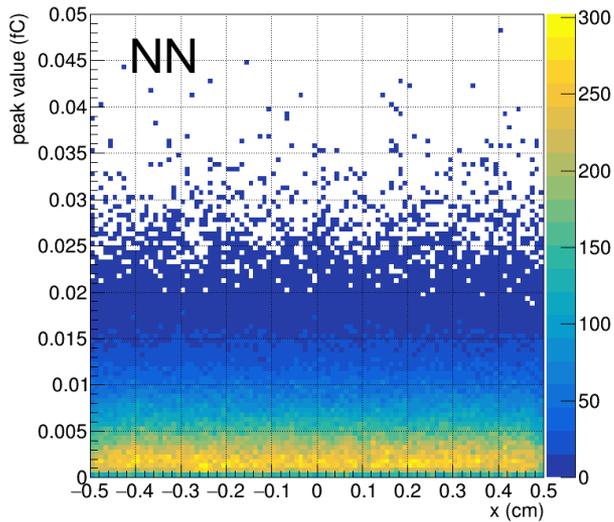
- ❖ Simulating single electron pulse  $\approx$  simulating peak\_time and peak\_value of the pulse + using pulse template

# ML for peak time and value simulation

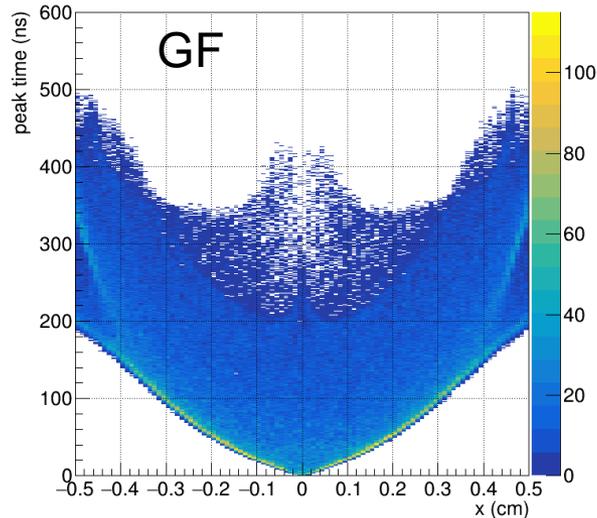
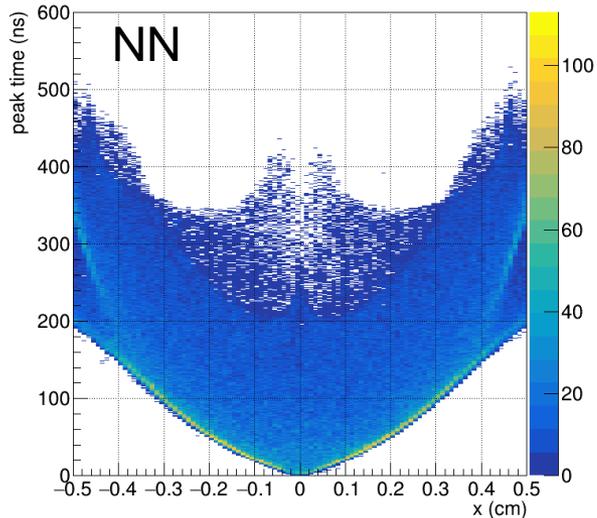
- ❖ Model: deep neural network (DNN)
  - Consist of input, hidden, and output layers
- ❖ Input data:
  - Local x and y positions of ionized electrons
  - $N(0,1)$  distribution noise
- ❖ Output: peak time and value of single electron pulse
- ❖ Loss: two sample test statistics (SmoothKNN) between real data and generated data



# ML simulation of peak time and value



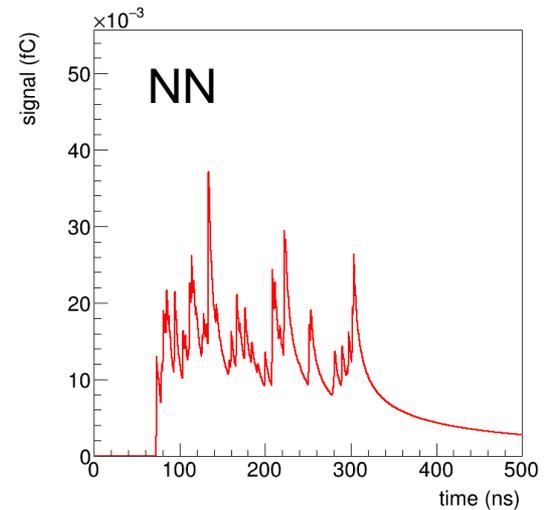
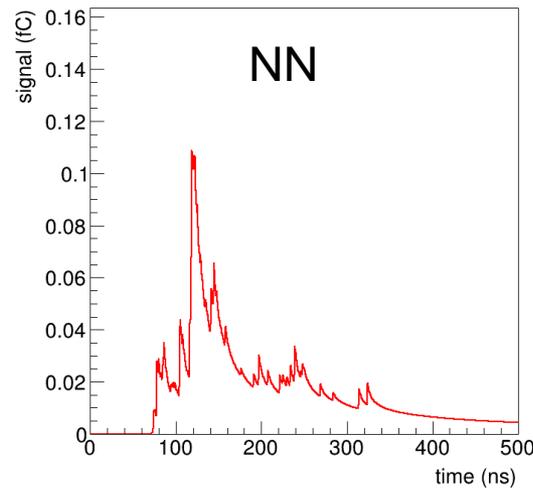
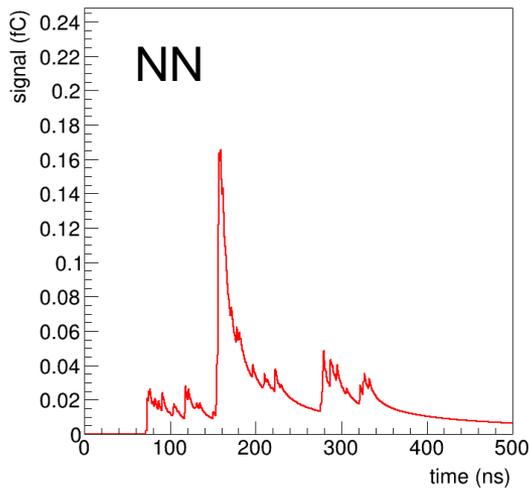
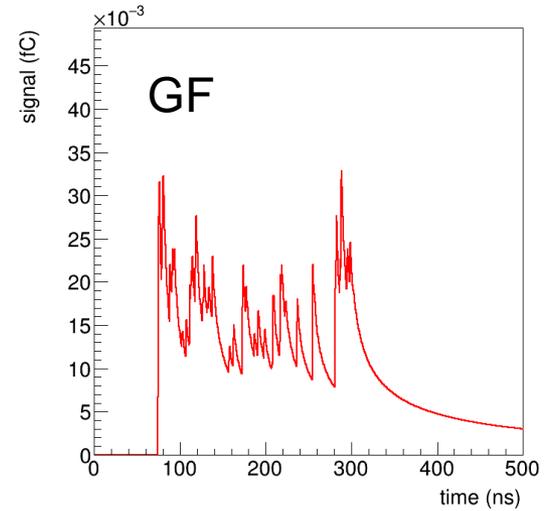
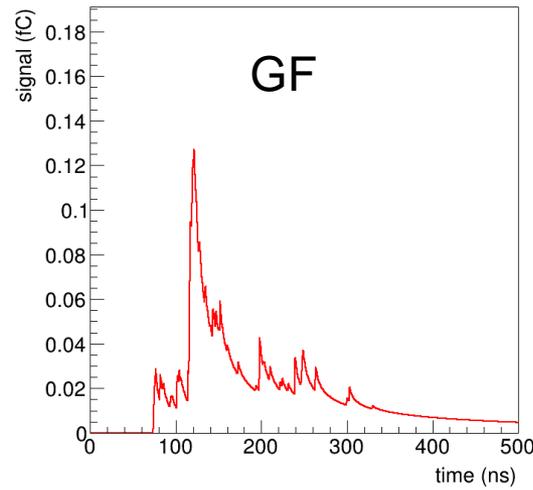
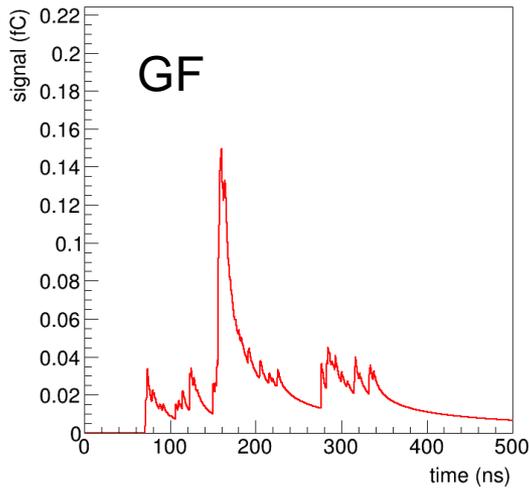
Peak value vs x



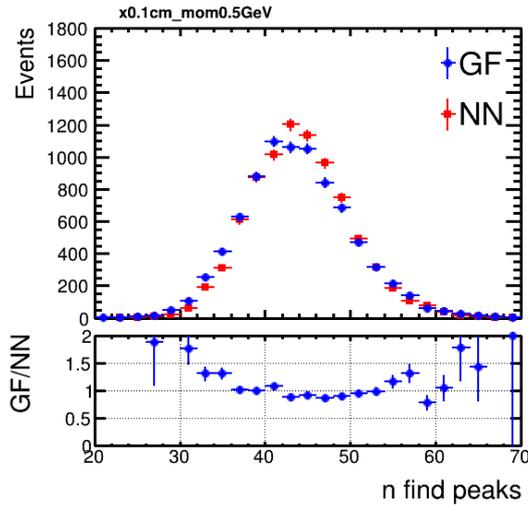
Peak time vs x

# Display of signal response

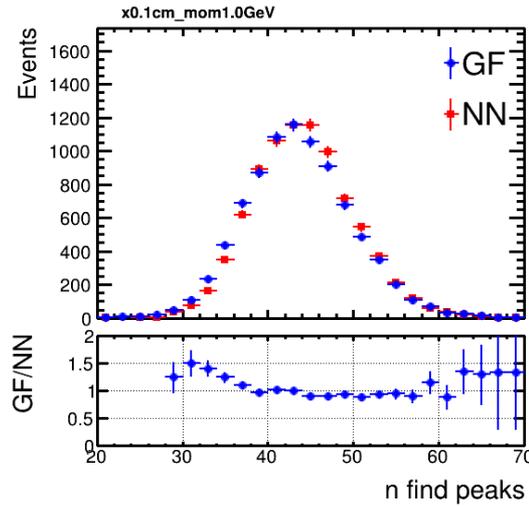
□ 1GeV  $\pi^-$



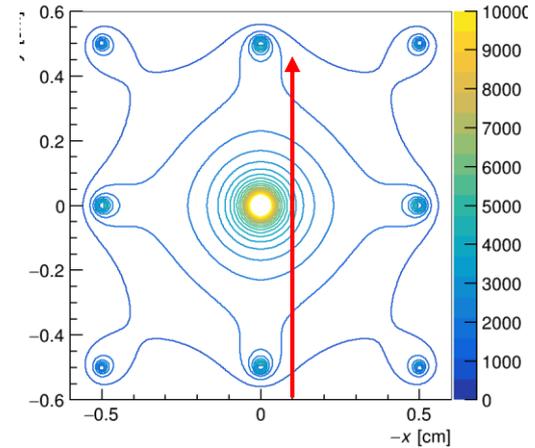
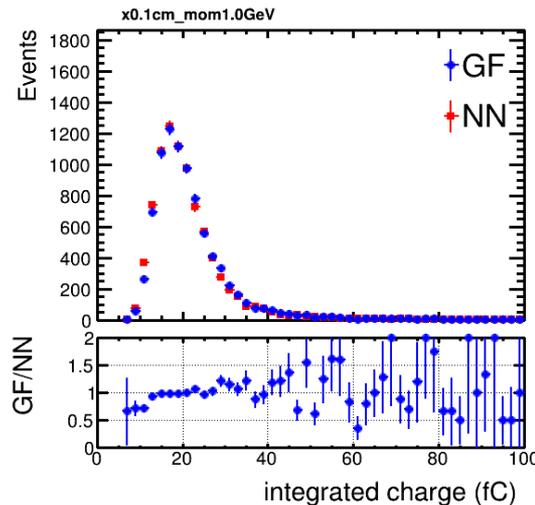
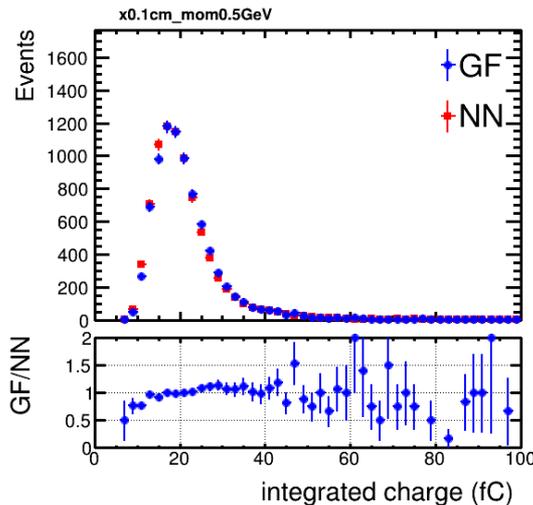
# Performance check: electron ( $x=0.1$ cm)



0.5 GeV

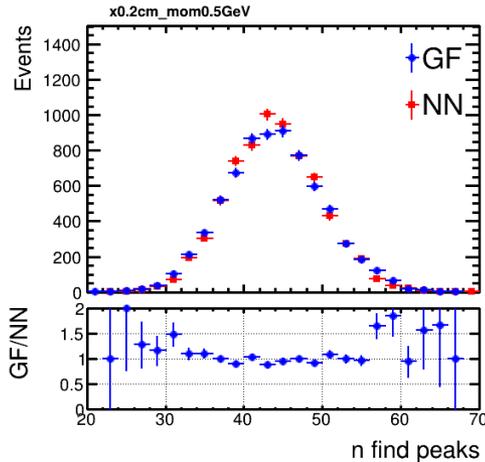


1 GeV

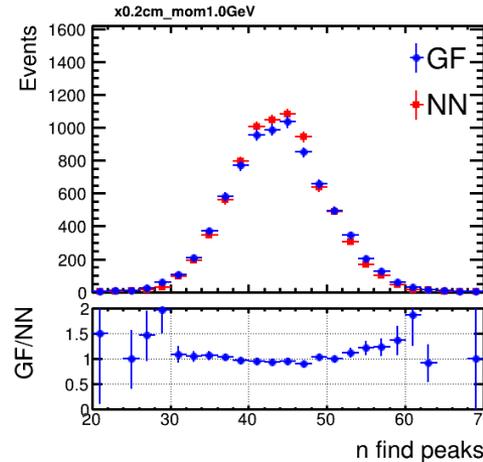


- ❖ Checked the number of found peaks ([scipy.signal.find\\_peaks](https://docs.scipy.org/doc/scipy/reference/generated/scipy.signal.find_peaks.html)) and total charge
- ❖ Good agreement in general
- ❖ Similar results for 5 and 10 GeV

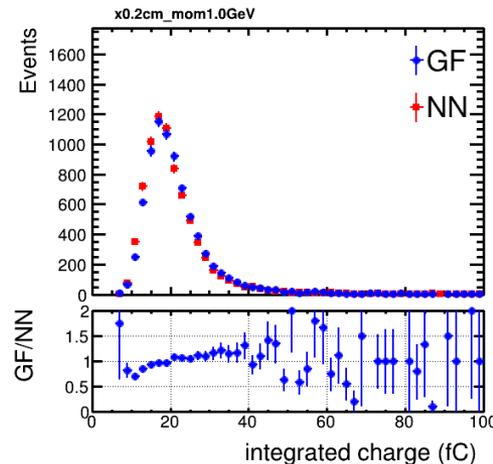
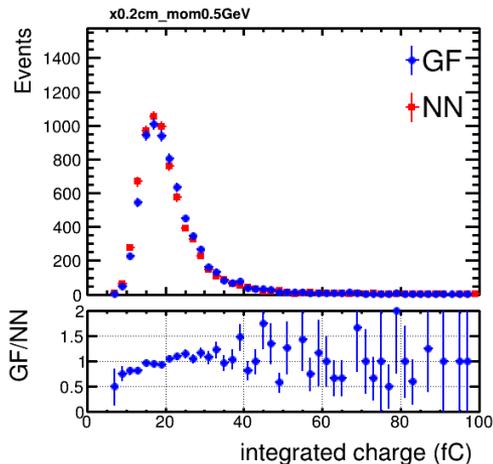
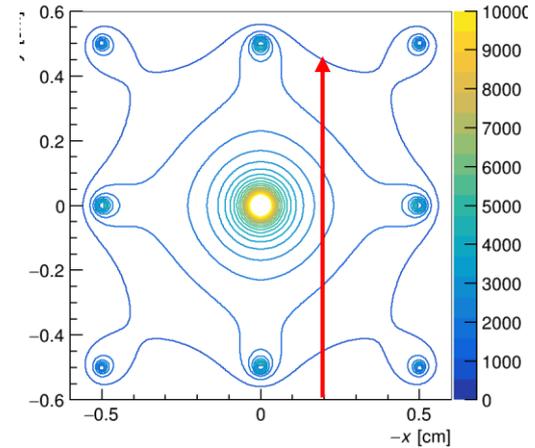
# Performance check: electron ( $x=0.2$ cm)



0.5 GeV

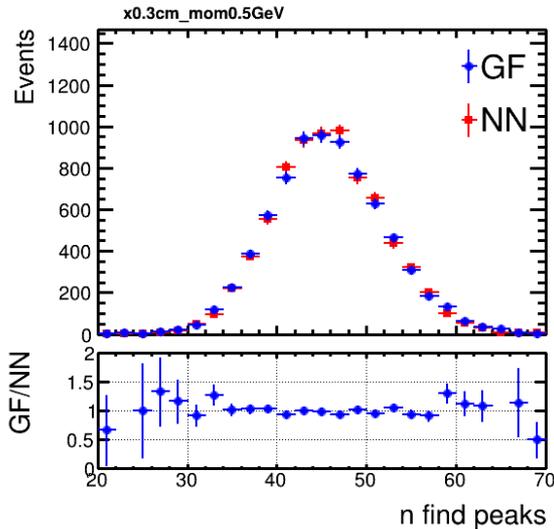


1 GeV

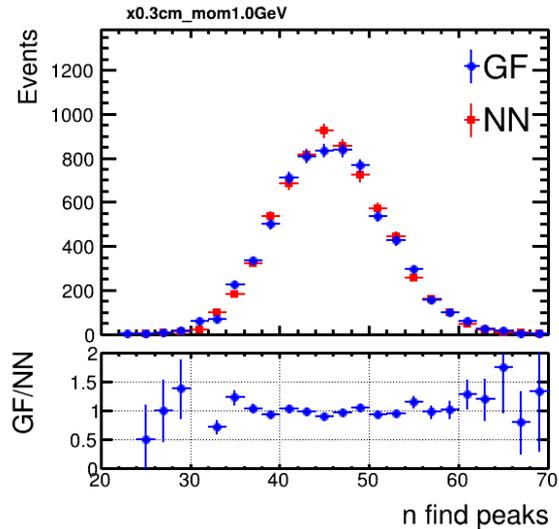


- ❖ Good agreement in general
- ❖ Similar results for 5 and 10 GeV

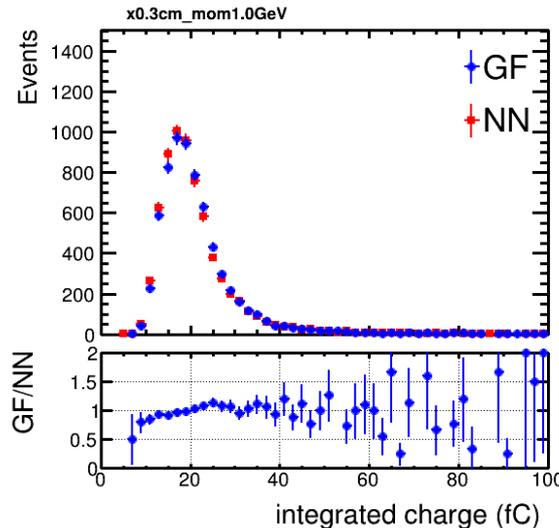
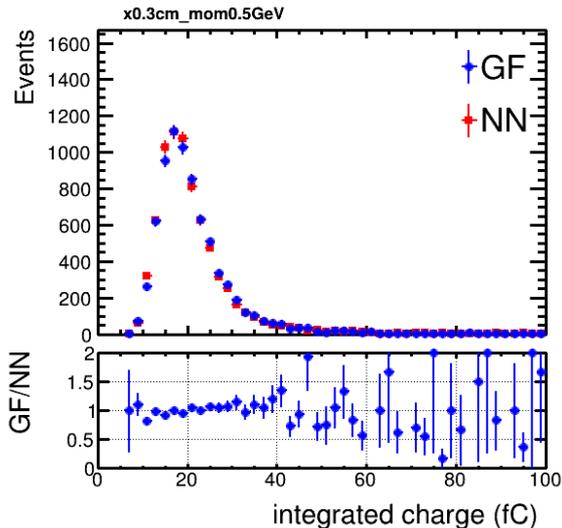
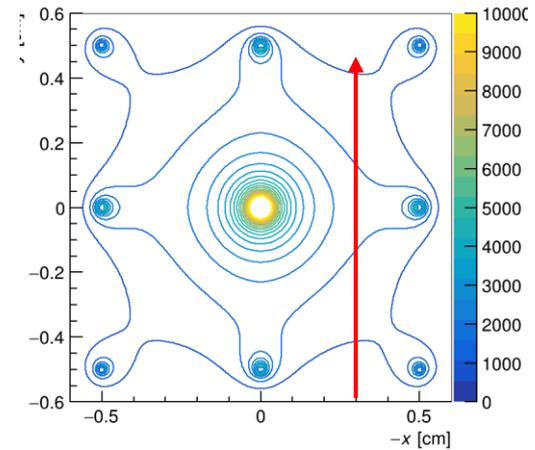
# Performance check: electron ( $x=0.3$ cm)



0.5 GeV

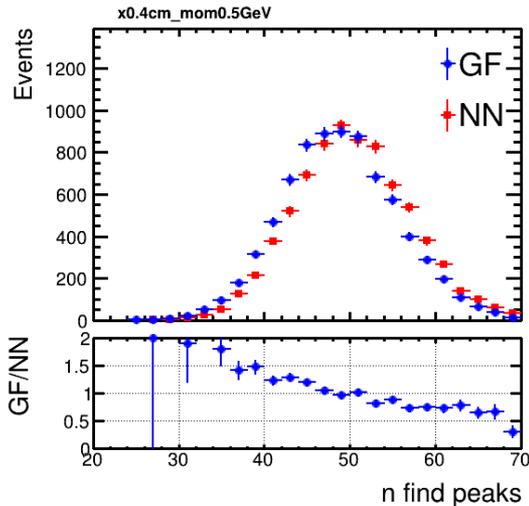


1 GeV

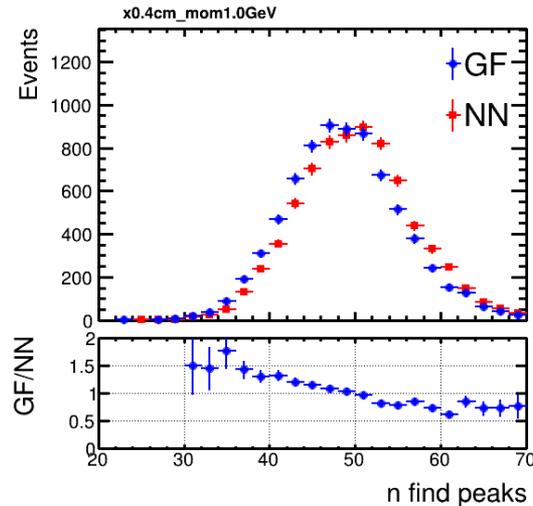


- ❖ Good agreement in general
- ❖ Similar results for 5 and 10 GeV

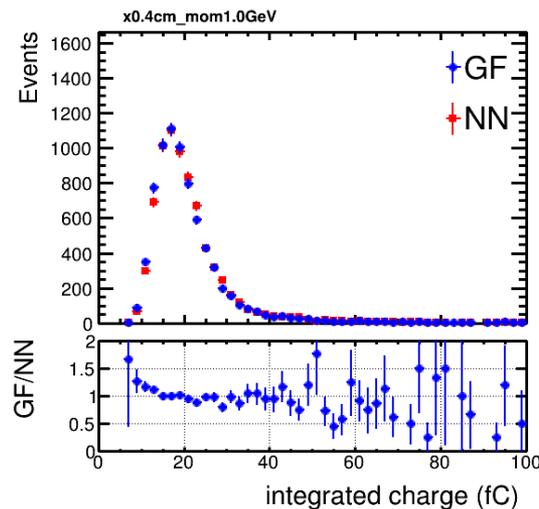
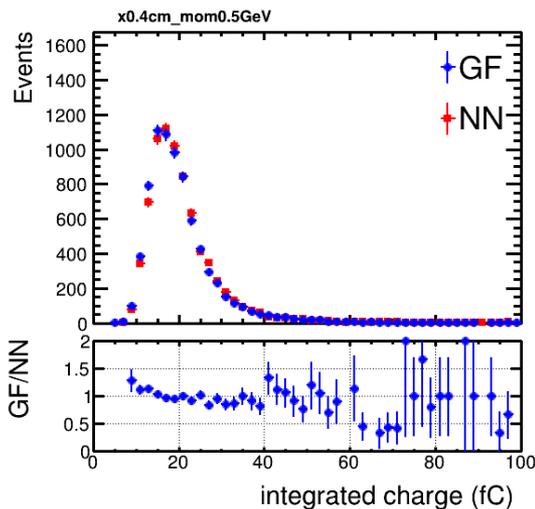
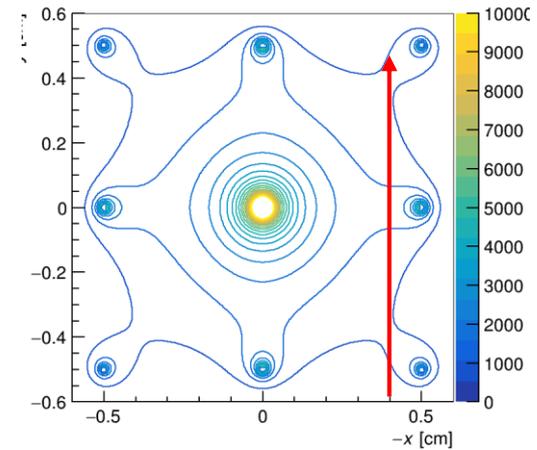
# Performance check: electron ( $x=0.4$ cm)



0.5 GeV



1 GeV



- ❖ A little bias for number of found peaks. Have space for improvement
- ❖ Similar results for 5 and 10 GeV

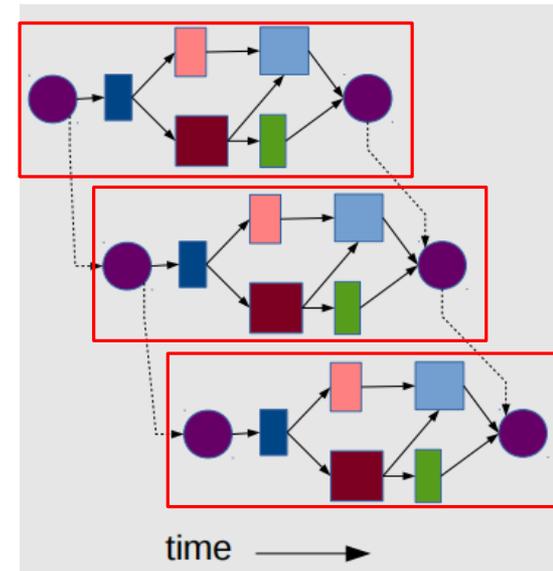
# Simulation time

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- ❑ Average time for one cell ( $1 \times 1\text{cm}^2$ ) simulation for 1 GeV  $\pi^-$  (gas: 50 He + 50C<sub>4</sub>H<sub>10</sub>) :
  - ❑ Garfield++: ~250 s
  - ❑ NN: ~1 s
- ❑ This simulation algorithm is general and applicable for different particles. As for different particles, only the ionization part is different, the signal response simulation keeps the same
- ❑ By this way, pulse simulation is not related to Geant4 and it is independent between each electron. To further speed up the signal response simulation, GPU or multithreading technique can be easily used

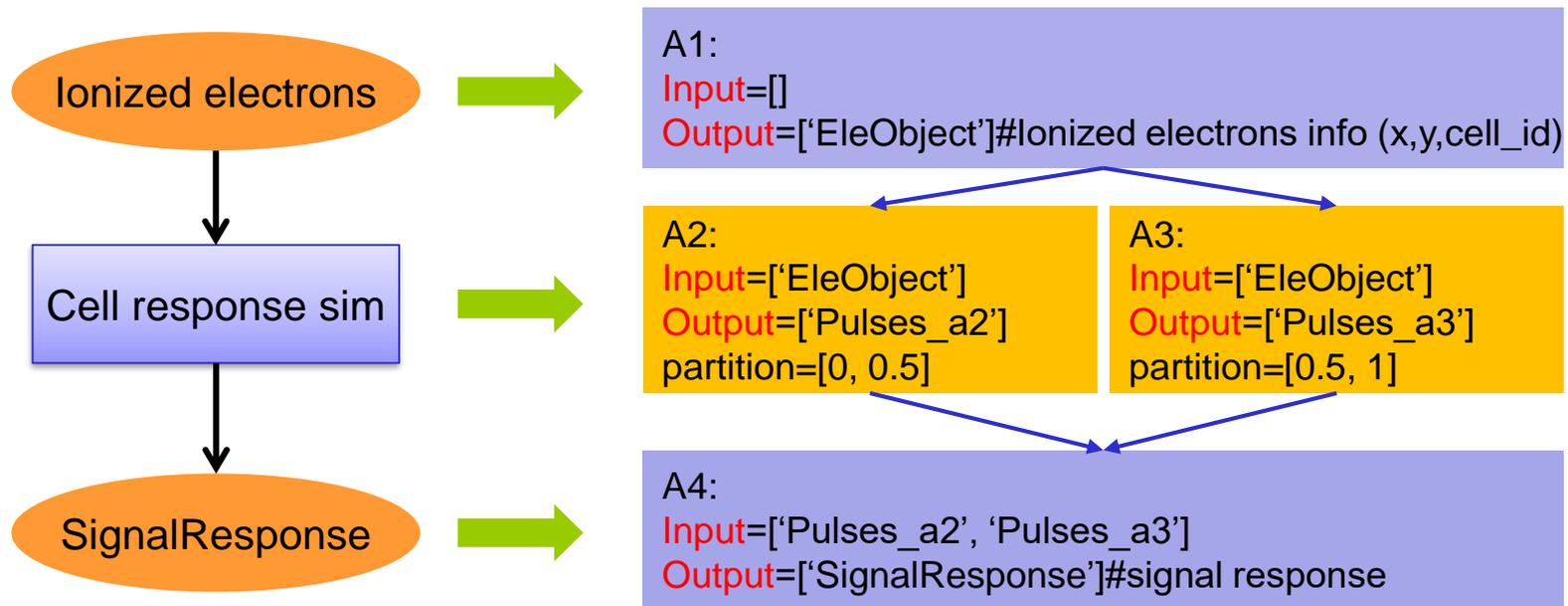
# Gaudi Hive

- ❖ Gaudi Hive: multi-threaded, concurrent extension to Gaudi
- ❖ Data Flow driven mechanism
  - Algorithms declare their data dependencies
    - build a directed acyclic graph - can be used for optimal scheduling
  - Scheduler automatically executes Algorithms as data becomes available
- ❖ Algorithms process events in their own thread
- ❖ Multiple algorithms and events can be executed simultaneously
- ❖ Algorithm Cloning
  - Multiple instances of the same Algorithm can exist, and be executed concurrently, each for different event



# Example using dummy data object

- ❖ Performing the study using dummy data object



- ❖ Working well

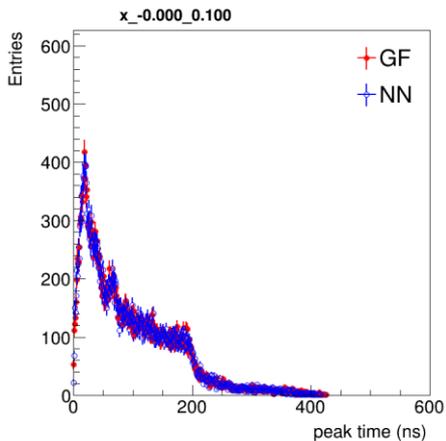
# Summary and plan

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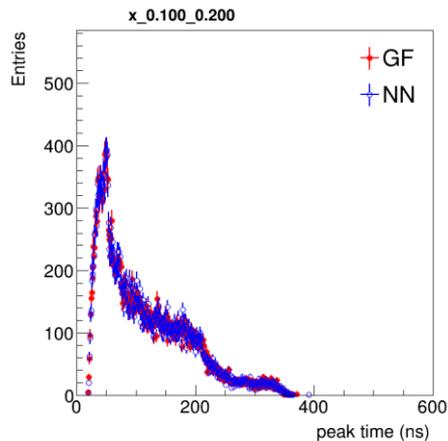
- ❖ A new simulation scheme for drift chamber has been presented
- ❖ The ionization simulation using Geant4 combined with TrackHeed have been implemented in CEPCSW. Results are consistent with Garfield++ simulation
- ❖ In order to speed up the simulation of signal response, a fast simulation method using ML has been implemented, which gives good agreement with Garfield++ simulation results
- ❖ Multi-threaded simulation of drift chamber has been studied with Gaudi Hive
- ❑ Future plan:
  - Improving the performance of fast signal simulation for some regions
  - Providing multi-threaded solution by combining Geant4 and the simulation with ML

Back up

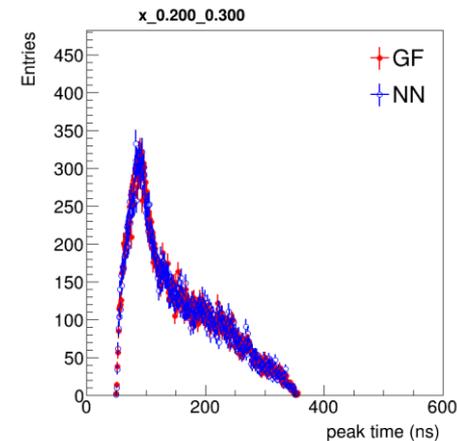
# Peak time simulation



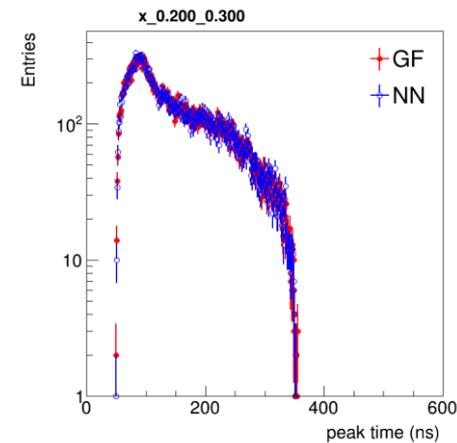
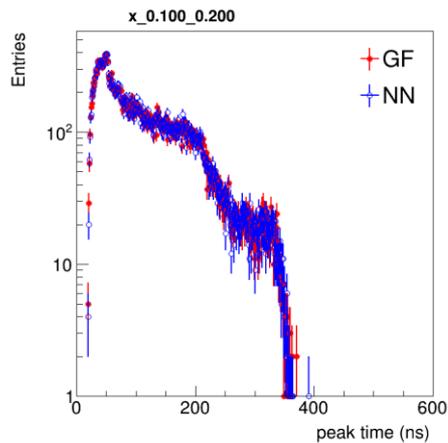
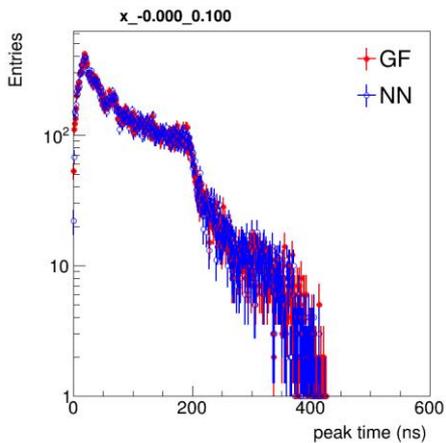
x(0,0.1) cm



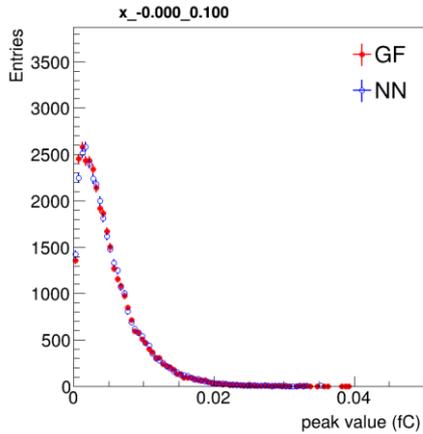
x(0.1,0.2) cm



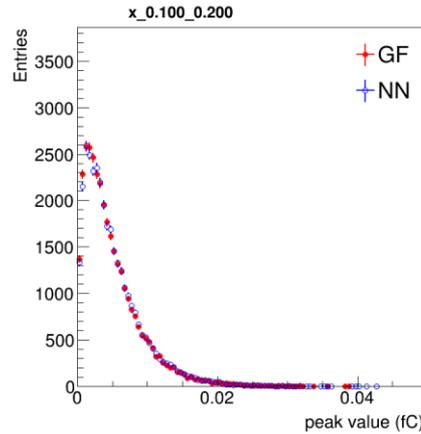
x(0.2,0.3) cm



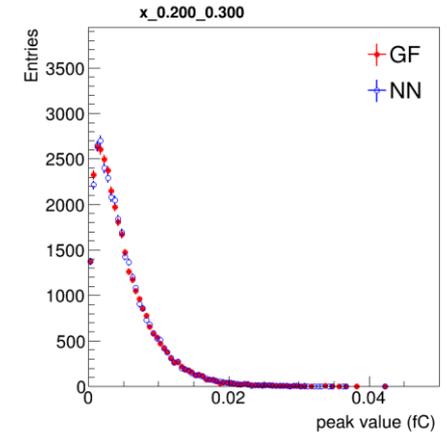
# Peak value simulation



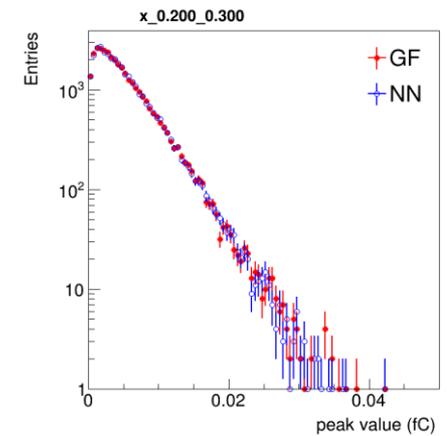
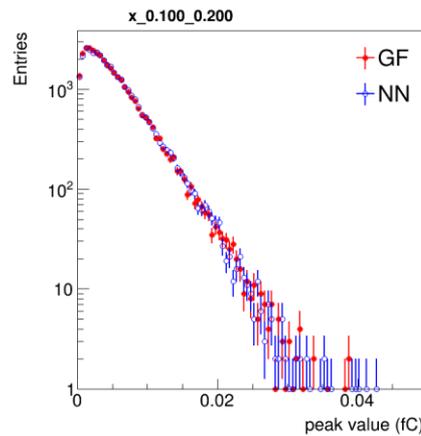
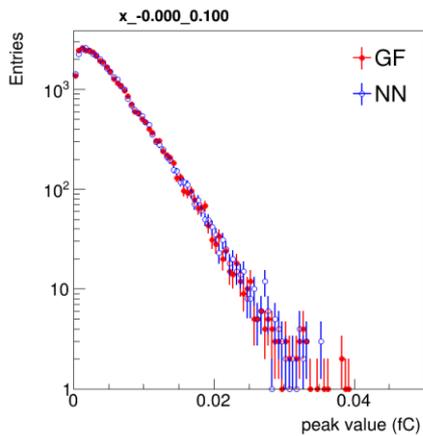
x(0,0.1) cm



x(0.1,0.2) cm

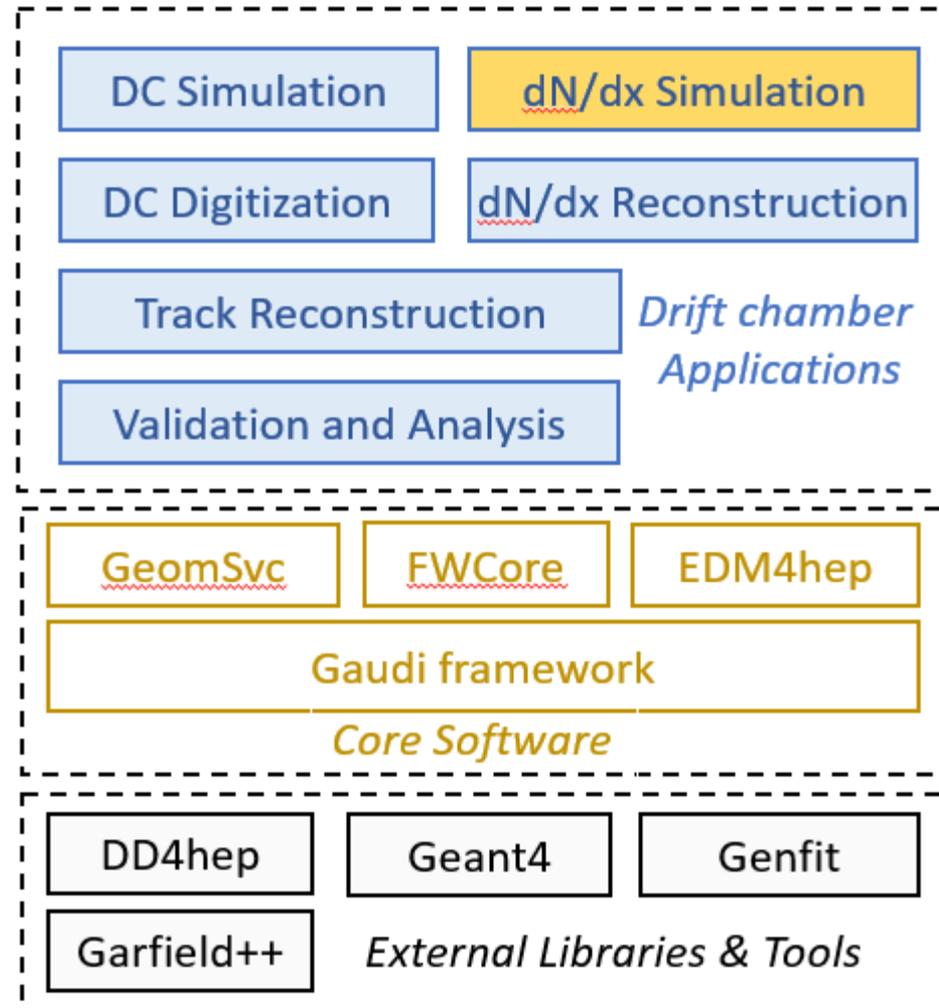


x(0.2,0.3) cm



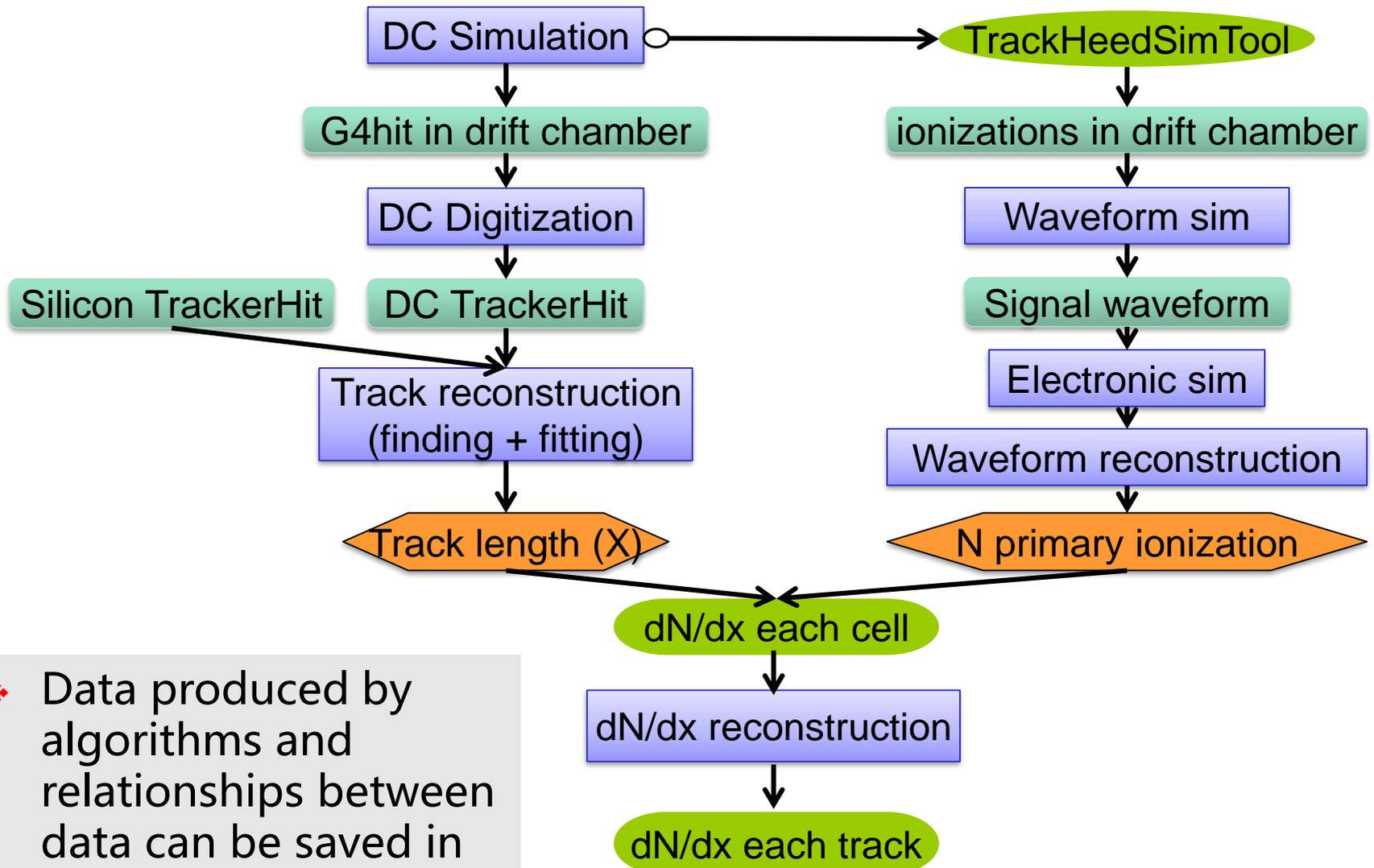
# CEPCSW for drift chamber

- ❖ Framework:
  - Gaudi
- ❖ EDM:
  - Key4hep::EDM4hep
  - Key4hep::FWCore
- ❖ Detector geometry and B field:
  - Key4hep::DD4hep
  - GeomSvc
- ❖ Drift chamber:
  - DC simulation (Geant4)
  - DC digitization
  - Track reconstruction (Genfit)
  - dN/dx simulation (Garfield++)
  - dN/dx reconstruction



<https://github.com/cepc/CEPCSW>

# Schema of dN/dx study in CEPCSW



- ❖ Data produced by algorithms and relationships between data can be saved in EDM4hep for analysis

- 
- ❖ The Gaudi Hive is studied for multithreaded simulation of drift chamber
  - ❖ User defined or edm4hep format data is supported in Gaudi Hive
  - ❖ Using Gaudi::Functional instead of Algorithm have been tried, finding problems with edm4hep data, under investigation

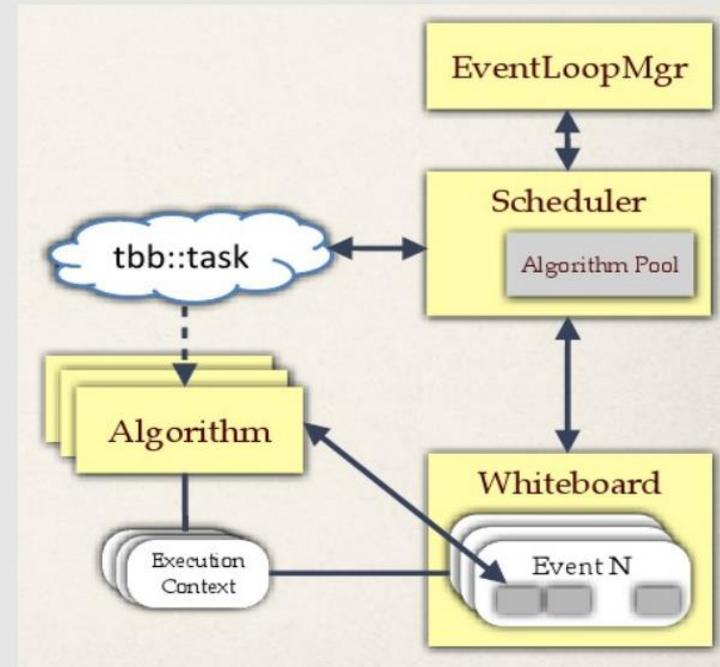
❑ Future plan:

- Try to write the output to root files
- Combining with Geant4 simulation
- Integrating with k4FWCore, maybe develop a multithreading version of k4FWCore
- Creating a prototype of CEPCSW based on GaudiHive

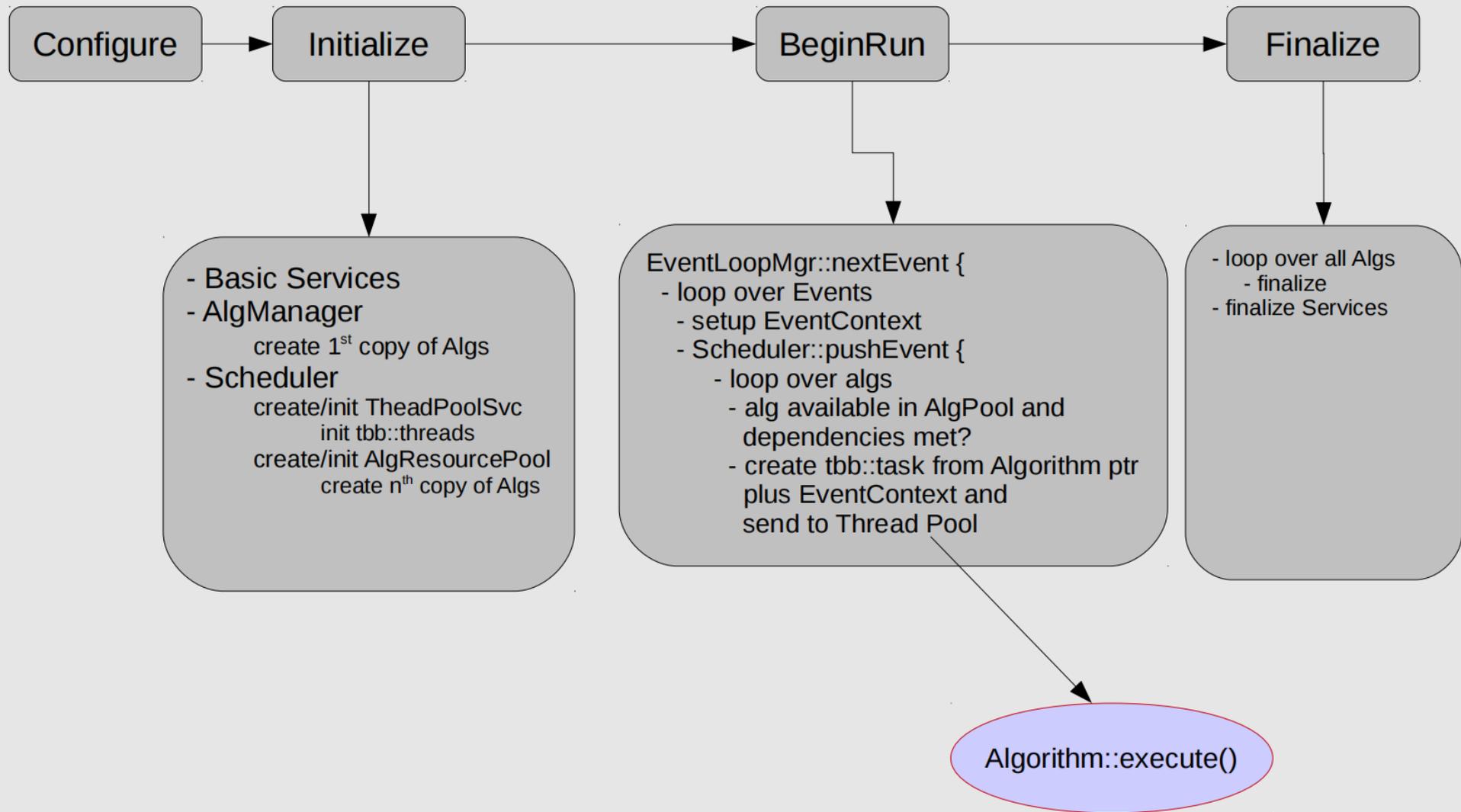
❑ Welcome to check the code:

<https://github.com/wenxingfang/DCMTSim>

- Configuration, Initialization, Finalization are performed serially in "master" thread
  - ▶ only Algorithm::execute is concurrent
- Algorithms are scheduled when data becomes available
  - ▶ Algorithms must declare their inputs at initialization or dynamically with DataHandles
  - ▶ tbb::task wraps the pair (Algorithm\*, ExecutionContext)
- Several instances of the same Algorithm can co-exist
  - ▶ **cloning**: create new instance if can be scheduled, and all other instances busy
  - ▶ running on different events
  - ▶ managed by AlgoPool



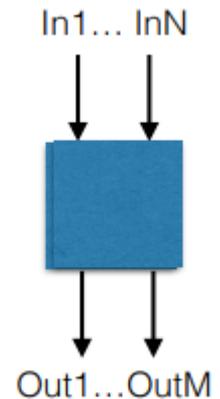
- Multiple events are managed simultaneously
  - ▶ increases probability of scheduling an Algorithm
  - ▶ whiteboard DataStore is thread safe



# Gaudi::Functional

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- ❖ Most algorithms look like “some data in” -> “some data out”
- ❖ Standardize the common pattern of getting data out of the TES, working on it, and putting it back in (in a different location).
  - Less code to write
  - More uniform code and easy to understand
  - Can be Re-Entrant, no need for clone, save memory
  - Multithreading friendly
- ❖ Patterns available:
  - Consumer, Producer, Filter, Transformer, MultiTransformer, ScalarTransformer, ...



# Re-Entrant test

## ❖ Gaudi::Functional Re-Entrant test

```
class DataMaker_v1 : public Gaudi::Functional::Producer<std::vector<float>()> {
public:
    DataMaker_v1(const std::string& name, ISvcLocator* svcLoc)
        : Producer( name, svcLoc,
            KeyValue("OutputLocation", {"MyVec_v1"})) {
        std::string bp_file = "/junofs/users/wxfang/MyGit/tmp/check_G4FastSim_20210
        char* cstr = new char[bp_file.size() + 1];
        strcpy(cstr, bp_file.c_str());
        m_NNPred = new NNPred(cstr);
    }
    std::vector<float> operator()() const override;
protected:
    NNPred* m_NNPred;
};
```

- ❑ Gaudi::Functional is re-entrantable
- ❑ The pytorch model is re-entrantable

```
evtslots = 10
```

```
whiteboard = HiveWhiteBoard("EventDataSvc", EventSlots=evtslots)
```

```
slimeventloopmgr = HiveSlimEventLoopMgr(OutputLevel=DEBUG)
```

```
scheduler = AvalancheSchedulerSvc(ThreadPoolSize=8, OutputLevel=WARNING)
```

```
a1 = DataMaker_v1()
```

```
ApplicationMgr(
    EvtMax=100,
    EvtSel='NONE',
    ExtSvc=[whiteboard],
    EventLoop=slimeventloopmgr,
    TopAlg=[a1],
    HistogramPersistency = "ROOT",
    MessageSvcType="InertMessageSvc")
```

```
HiveSlimEventLo... DEBUG createdEvts: 5, freeslots: 6
DataMaker_v1      INFO executing DataMaker_v1
HiveSlimEventLo... DEBUG work loop iteration 7
HiveSlimEventLo... DEBUG createdEvts: 6, freeslots: 5
DataMaker_v1      INFO executing DataMaker_v1
HiveSlimEventLo... DEBUG work loop iteration 8
DataMaker_v1      INFO executing DataMaker_v1
HiveSlimEventLo... DEBUG createdEvts: 7, freeslots: 4
DataMaker_v1      INFO executing DataMaker_v1
HiveSlimEventLo... DEBUG work loop iteration 9
HiveSlimEventLo... DEBUG createdEvts: 8, freeslots: 3
DataMaker_v1      INFO executing DataMaker_v1
HiveSlimEventLo... DEBUG work loop iteration 10
DataMaker_v1      INFO executing DataMaker_v1
HiveSlimEventLo... DEBUG createdEvts: 9, freeslots: 2
HiveSlimEventLo... DEBUG work loop iteration 11
HiveSlimEventLo... DEBUG createdEvts: 10, freeslots: 1
DataMaker_v1      INFO executing DataMaker_v1
HiveSlimEventLo... DEBUG work loop iteration 12
HiveSlimEventLo... DEBUG Draining the scheduler
HiveSlimEventLo... DEBUG Waiting for a context
DataMaker_v1      INFO executing DataMaker_v1
```

# Using Gaudi::Functional

A1 = MakerIons("IonsProducer")  
A1.OutputLocation="/Event/MyIons"

```
class MakerIons : public Gaudi::Functional::Producer<IonVec()> {  
public:  
    MakerIons(const std::string& name, ISvcLocator* svcLoc)  
        : Producer( name, svcLoc,  
            KeyValue("OutputLocation", {"MyIonVec"})) {}  
  
    IonVec operator()() const override;  
};
```

A2 = SimWF("SimA2")  
A2.InputLocation="/Event/MyIons"  
A2.OutputLocation="/Event/MySimA2"  
A2.partition=[0 ,0.5]

A3 = SimWF("SimA3")  
A3.InputLocation="/Event/MyIons"  
A3.OutputLocation="/Event/MySimA3"  
A3.partition=[0.5 ,1]

```
struct IonVec{  
    int data;  
    std::vector<int> cell_id;  
    std::vector<float> x;  
    std::vector<float> y;  
};
```

A4 = MergeWF("MergeWF")  
A4.InputLocations=["/Event/MySimA2", "/Event/MySimA3"]  
A4.OutputLocation="/Event/MyMergeWF"

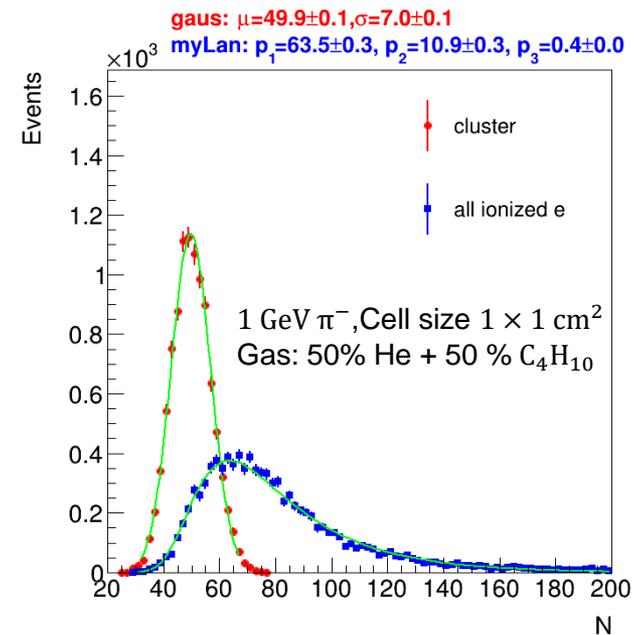
```
struct WFVec{  
    int data;  
    std::vector<int> e_id;  
    std::vector<int> cell_id;  
    std::vector<float> peak_time;  
    std::vector<float> peak_value;  
    std::vector<std::vector<float>> charges;  
};
```

```
using BaseClass_t = Gaudi::Functional::Traits::BaseClass_t<Gaudi::Algorithm>;  
struct SimWF final : Gaudi::Functional::Transformer<WFVec( const IonVec& ), BaseClass_t> {  
  
    SimWF( const std::string& name, ISvcLocator* svcLoc )  
        : Transformer( name, svcLoc, KeyValue( "InputLocation", "/Event/MyInt" ),  
            KeyValue( "OutputLocation", "/Event/MyFloat" ) ) {}  
  
    WFVec operator()( const IonVec& input ) const override {
```

```
struct MergeWF final : Gaudi::Functional::MergingTransformer<WFVec( const Gaudi::Functional::vector_of_const_<WFVec>& ), BaseClass_t> {  
  
    MergeWF( const std::string& name, ISvcLocator* svcLoc )  
        : MergingTransformer( name, svcLoc, {"InputLocations", {}}, {"OutputLocation", "/Event/MyConcatenatedIntVector"} ) {}  
  
    WFVec operator()( const Gaudi::Functional::vector_of_const_<WFVec>& input ) const override {
```

# Motivation

- ❑ The particle identification is very important for CEPC flavor physics study. Good hadron separation up to 20 GeV is essential
- ❑ Traditionally: using  $dE/dx$  method
  - ❑ Due to the production of delta electron, the deposited energy follows Landau distribution
  - ❑ Resolution is  $\sim 6\%$
- ❑ New technique: using  $dN/dx$  (cluster counting) method
  - ❑ The number of primary ionization follows Poisson distribution
  - ❑ Resolution could reaches  $< 3\%$
- ❑ The  $dN/dx$  technique will be widely explored in CEPC drift chamber detector



# Ionization simulation in gas

---

## ❑ Garfield++

- ❑ Using Heed PAI model to simulate the ionization in gas precisely
- ❑ Can simulate the drift and avalanche of electrons in gas
- ❑ The drift of ions to cathode can be simulated
- ❑ The induced current can be given
- ❑ It is useful to study and characterize the properties of gas detector with simple geometry but not for full drift chamber detector

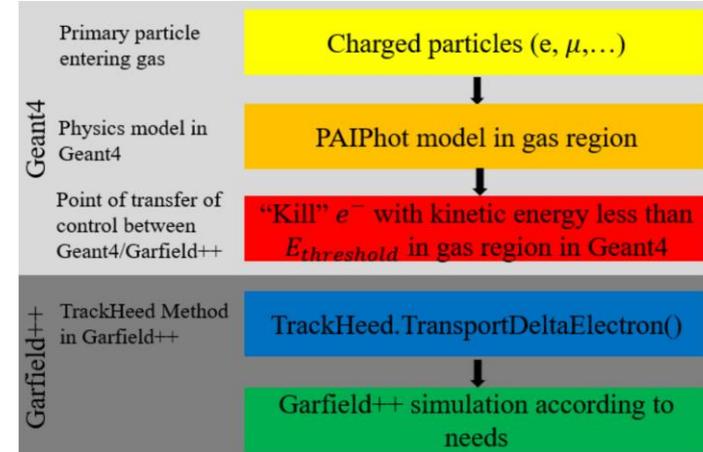
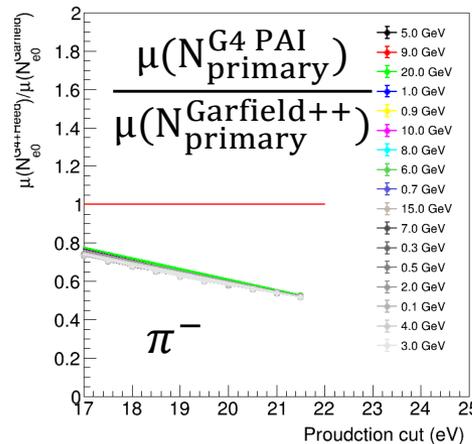
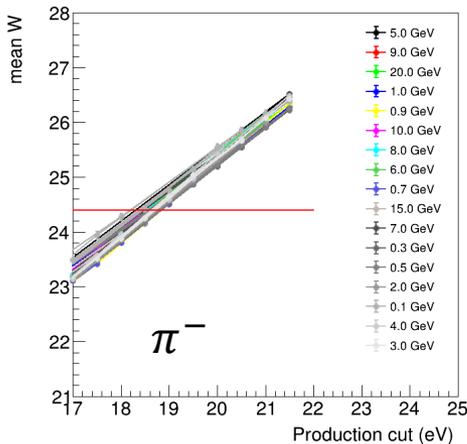
## ❑ Geant4

- ❑ Can simulate collider events and the interaction between particles and materials in full detector
- ❑ It does not simulate the ionization process properly, neither the drift and avalanche processes

- ❑ In order to simulate including particle interaction with detector materials, ionization in gas, drift and avalanche processes in full detector, we try to combine Geant4 and Garfield++ in CEPCSW<sub>4</sub>

# Ionization simulation in CEPCSW (G4 PAI)

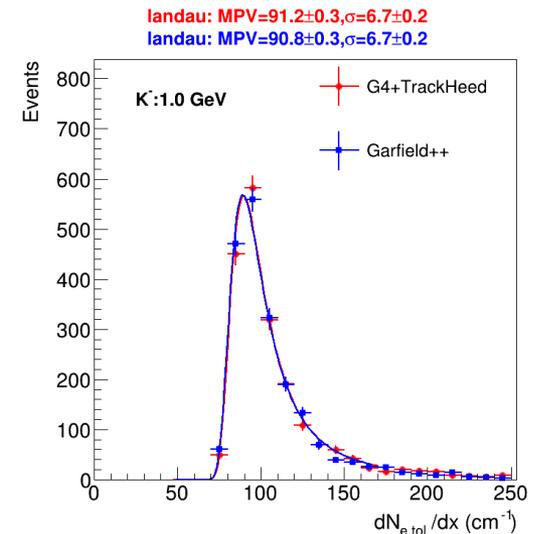
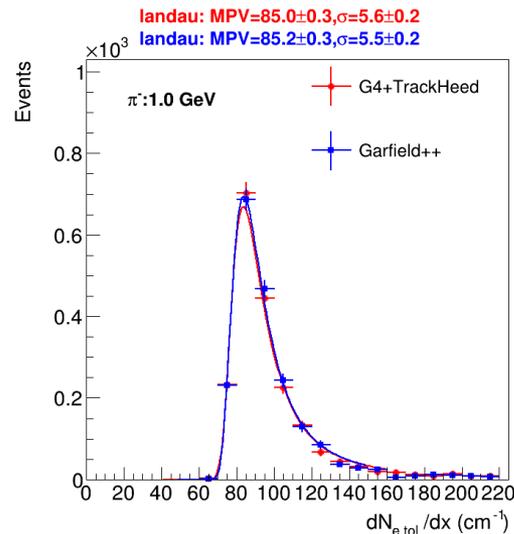
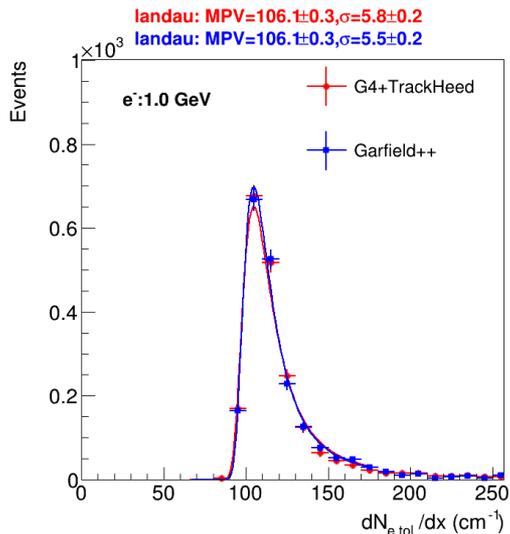
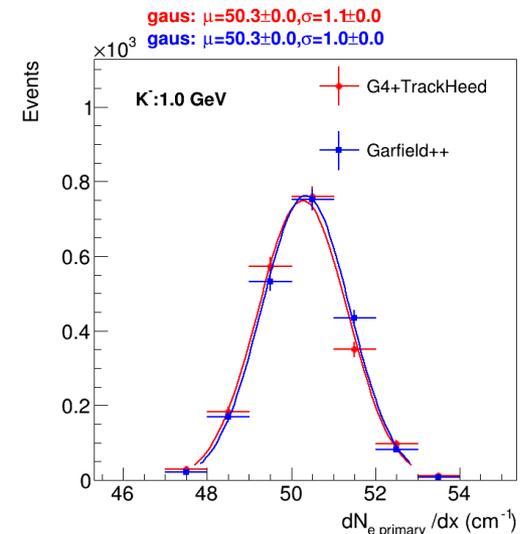
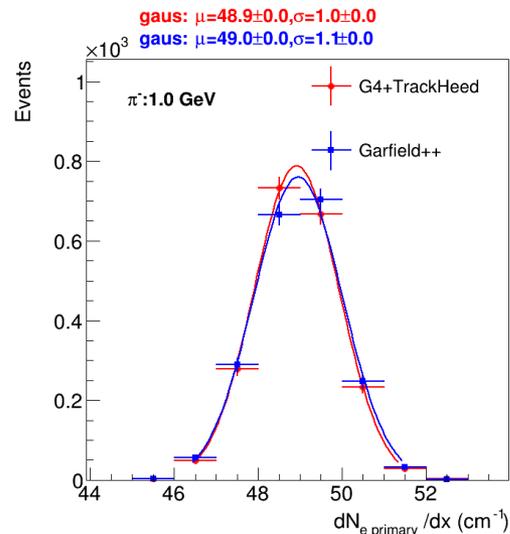
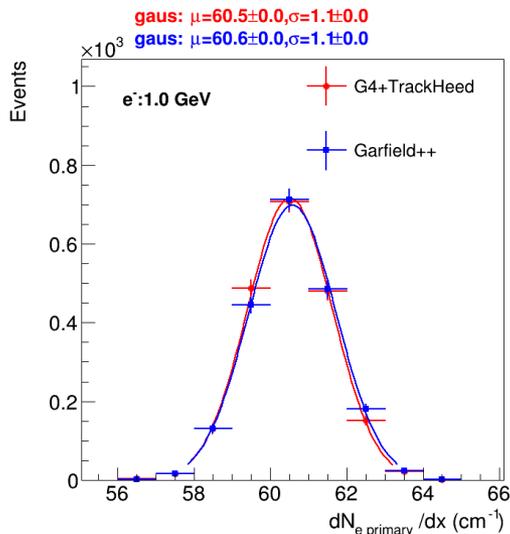
- ❖ First try: according to paper [“Interfacing Geant4, Garfield++ and Degrad for the Simulation of Gaseous Detectors”](#) :
  - Geant4 PAI model to simulate primary or secondary ionization
  - TrackHeed to simulate ionization from residual delta electron
- ❖ However, it was found that the primary ionization produced by this method is much less than Garfield++.



- ❖ Checking with authors:
  - This method designed to obtain correct energy deposition (or total ionizations)
  - It is true that this method will give less primary ionizations, so this method is obsolete

# Ionization simulation performance

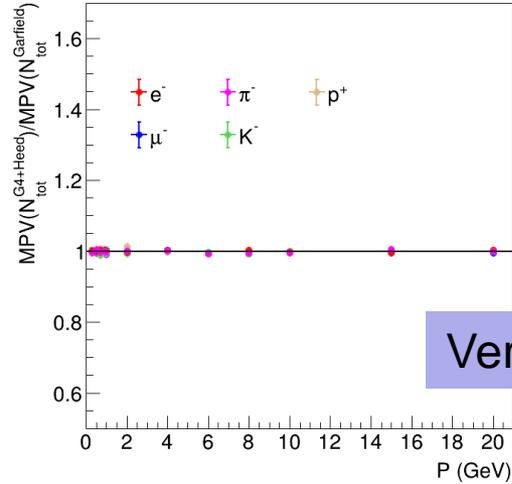
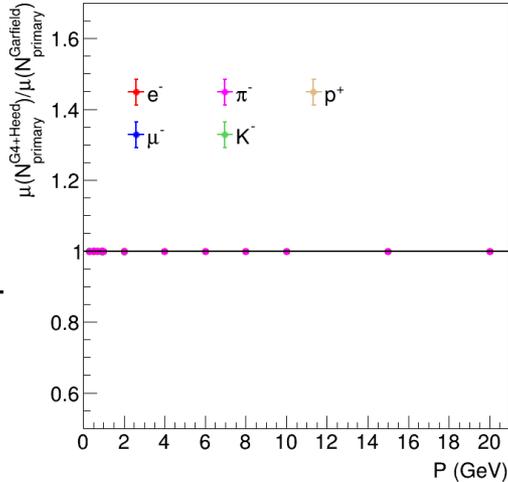
## ❖ Gas: 50% He + 50 % C<sub>4</sub>H<sub>10</sub>



# Ionization simulation performance

❖ Gas: 50% He + 50 % C<sub>4</sub>H<sub>10</sub>

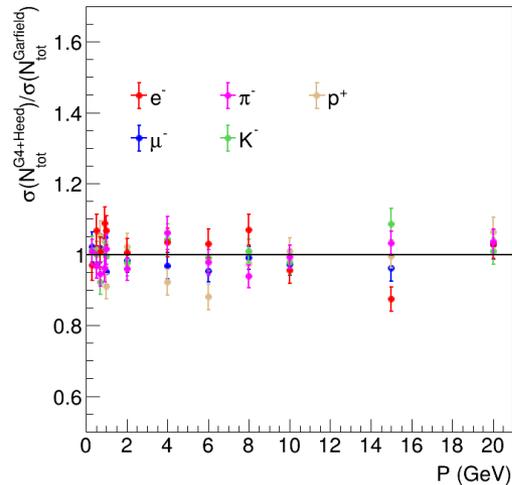
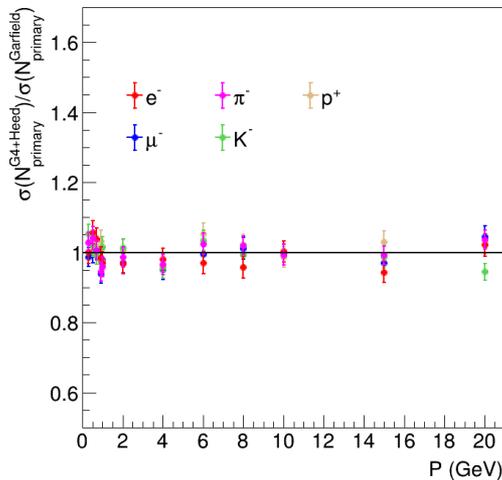
$$\frac{\mu(N_{\text{primary}}^{\text{G4+TrackHeed}})}{\mu(N_{\text{primary}}^{\text{Garfield++}})}$$



$$\frac{MPV(N_{\text{tot}}^{\text{G4+TrackHeed}})}{MPV(N_{\text{tot}}^{\text{Garfield++}})}$$

Very good agreement

$$\frac{\sigma(N_{\text{primary}}^{\text{G4+TrackHeed}})}{\sigma(N_{\text{primary}}^{\text{Garfield++}})}$$

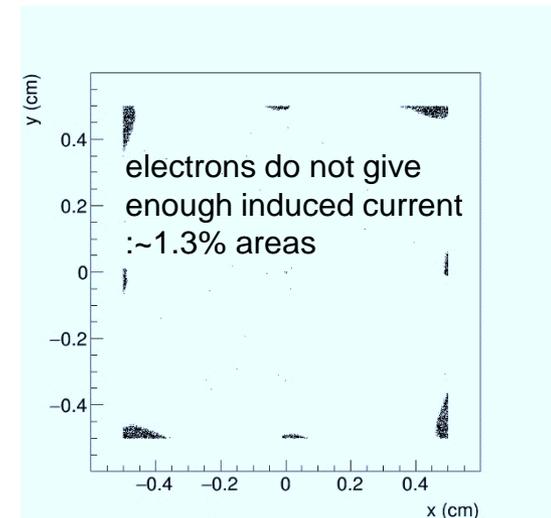
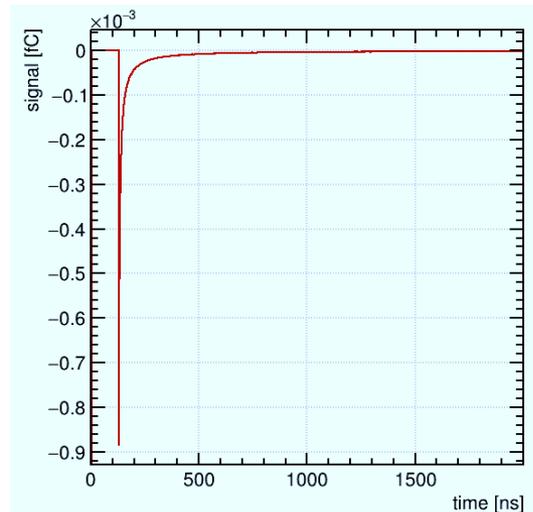
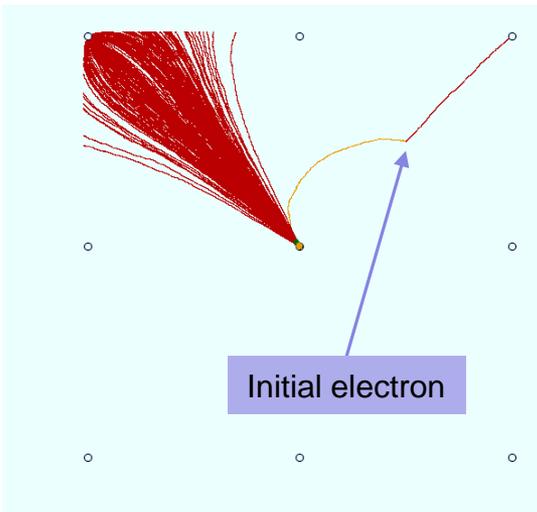
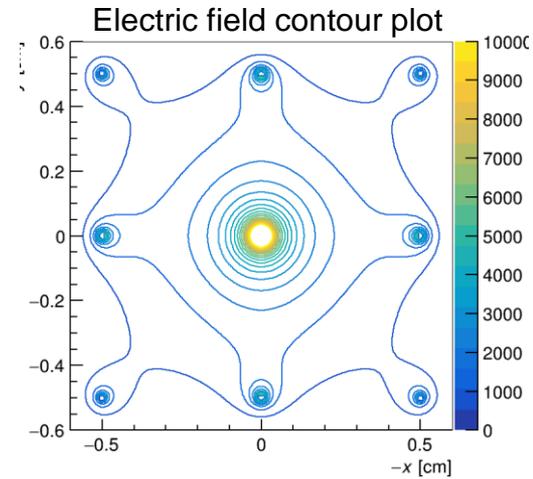


$$\frac{\sigma(N_{\text{tot}}^{\text{G4+TrackHeed}})}{\sigma(N_{\text{tot}}^{\text{Garfield++}})}$$

# Getting parameters from Garfield++

## ❖ Garfield++ simulation:

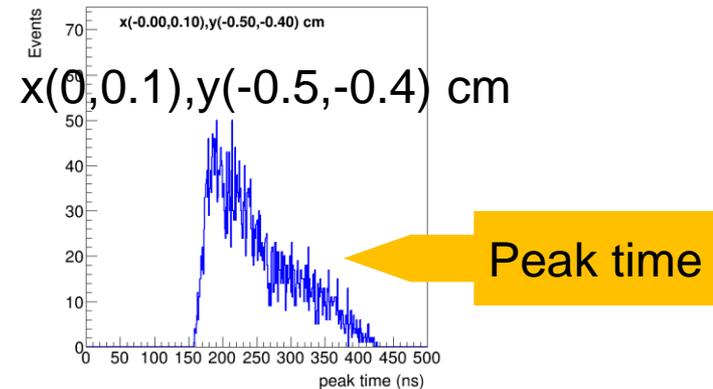
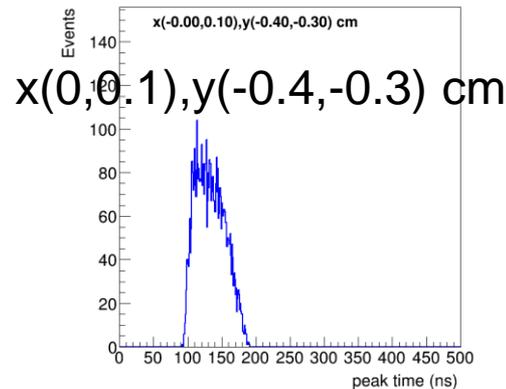
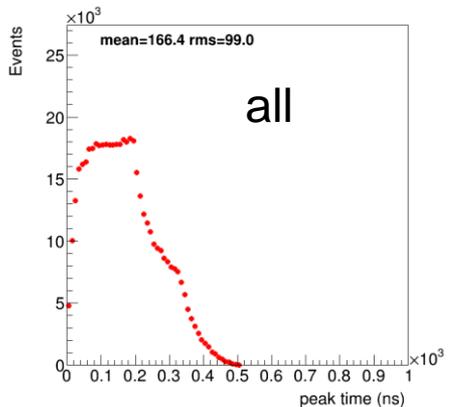
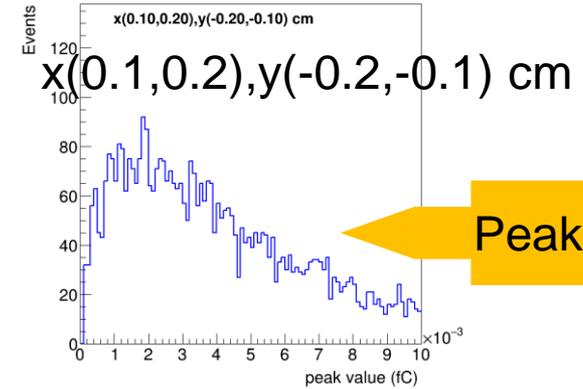
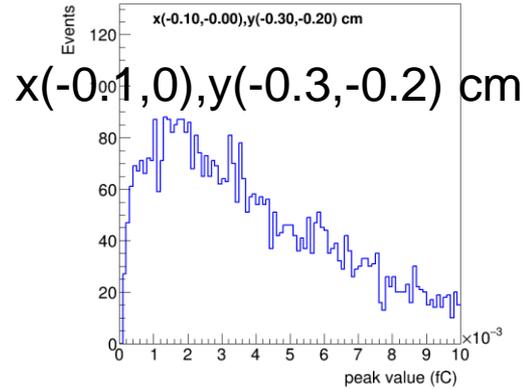
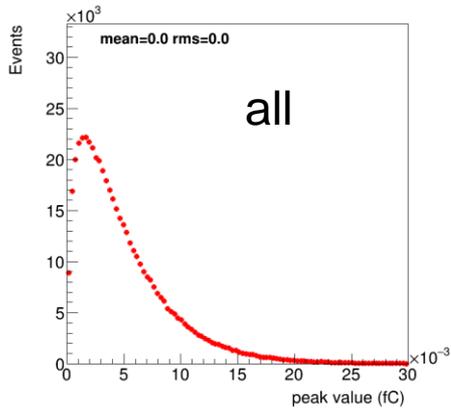
- 500k electrons uniformly distributed  $1 \times 1 \text{ cm}^2$  drift chamber cell
- Gas: 50% He + 50 %  $\text{C}_4\text{H}_{10}$
- Center signal wire (2000 V), eight field wires (0 V)



- One electron drift and avalanche
- Ions drift

Induced current

# Garfield++ simulation

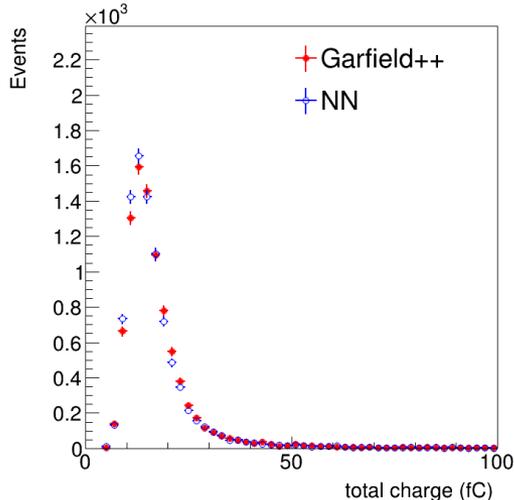
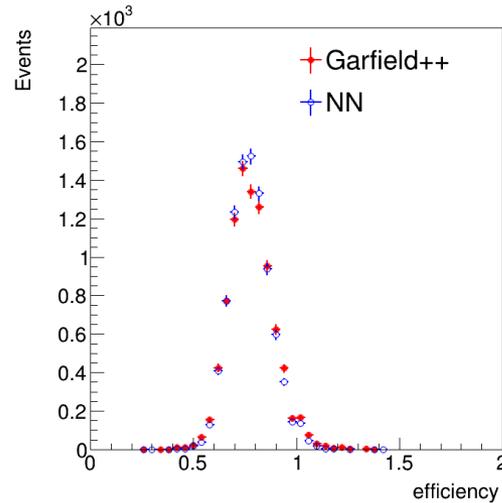
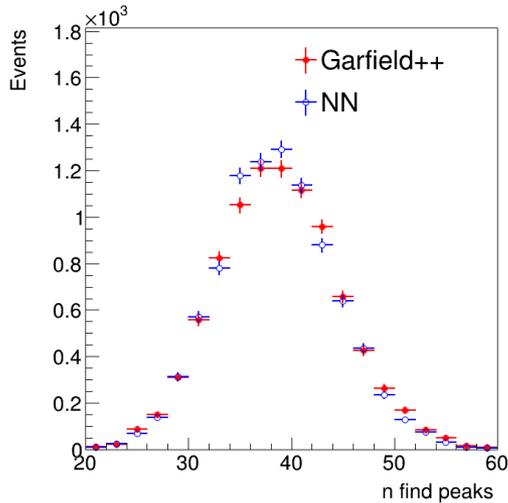


## ❖ Simulate (peak\_time, peak\_value):

- Sampling method base on which bin the electron (x,y) is located
- Machine learning method according electron (x, y) without binning <sup>39</sup>

# Signal waveform simulation

## □ 1GeV $\pi^-$



□ By this way, waveform simulation is not related to Geant4 and it is independent between each electron. Therefore, the waveform simulation can be transported to GPU or using multithreading technique to get speed up

- Good agreement between NN and Garfield++
- Average time for one cell simulation:
  - Garfield++: ~250 s
  - NN: ~1 s

□ For different particles, only the ionization part is different, the waveform simulation is the same